

150mA, Low-Dropout Regulator, Ultralow-Power, I_Q 1 μ A with Pin-Selectable, Dual-Level Output Voltage

FEATURES

- Low I_Q : 1 μ A
- 150mA, Low-Dropout Regulator with Pin-Selectable Dual Voltage Level Output
- Low Dropout: 200mV at 150mA
- 3% Accuracy Over Load/Line/Temperature
- Available in Dual-Level, Fixed Output Voltages from 1.5V to 4.2V Using Innovative Factory EPROM Programming
- Available in an Adjustable Version from 1.22V to 5.25V or a Dual-Level Output Version
- V_{SET} Pin Toggles Output Voltage Between Two Factory-Programmed Voltage Levels
- Stable with a 1.0 μ F Ceramic Capacitor
- Thermal Shutdown and Overcurrent Protection
- CMOS Logic Level-Compatible Enable Pin
- Available in DDC (TSOT23-5) or DRV (2mm × 2mm SON-6) Package Options

APPLICATIONS

- TI [MSP430](#) Attach Applications
- Power Rails with Programming Mode
- Dual Voltage Levels for Power-Saving Mode
- Wireless Handsets, Smartphones, PDAs, MP3 Players, and Other Battery-Operated Handheld Products

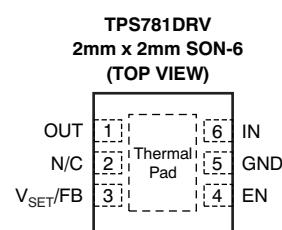
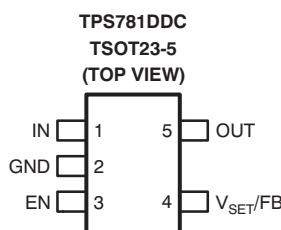
DESCRIPTION

The TPS781 family of low-dropout (LDO) regulators offer the benefits of ultralow power (I_Q = 1 μ A), miniaturized packaging (2×2 SON-6), and selectable dual-level output voltage levels. An adjustable version is also available, but does not have the capability to shift voltage levels.

The V_{SET} pin allows the end user to switch between two voltage levels *on-the-fly* through a microprocessor-compatible input. This LDO is designed specifically for battery-powered applications where dual-level voltages are needed. With ultralow I_Q (1 μ A), microprocessors, memory cards, and smoke detectors are ideal applications for this device.

The ultralow-power and selectable dual-level output voltages allow designers to customize power consumption for specific applications. Designers can now shift to a lower voltage level in a battery-powered design when the microprocessor is in sleep mode, further reducing overall system power consumption. The two voltage levels are preset at the factory through a unique architecture using an EPROM. The EPROM technique allows for numerous output voltage options between V_{SET} low (1.5V to 4.2V) and V_{SET} high (2.0V to 3.0V) in the fixed output version only. Consult with your local factory representative for exact voltage options and ordering information; minimum order quantities may apply.

The TPS781 series are designed to be compatible with the TI MSP430 and other similar products. The enable pin is compatible with standard CMOS logic. This LDO is stable with any output capacitor greater than 1.0 μ F. Therefore, implementations of this device require minimal board space because of miniaturized packaging and a potentially small output capacitor. The TPS781 series I_Q (1 μ A) also come with thermal shutdown and current limit to protect the device during fault conditions. All packages have an operating temperature range of T_J = -40°C to +125°C. For high-performance applications requiring a dual-level voltage option, consider the [TPS780 series](#), with an I_Q of 500nA and dynamic voltage scaling.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

All trademarks are the property of their respective owners.



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

ORDERING INFORMATION⁽¹⁾⁽²⁾

PRODUCT	V _{OUT}
TPS781vvvxxxxyyyz	VVV is the nominal output voltage for V _{OUT(HIGH)} and corresponds to V _{SET} pin low. XXX is the nominal output voltage for V _{OUT(LOW)} and corresponds to V _{SET} pin high. YYY is the package designator. Z is the tape and reel quantity (R = 3000, T = 250). Adjustable version ⁽³⁾⁽⁴⁾

- (1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.
- (2) Additional output voltage combinations are available on a quick-turn basis using innovative, factory EPROM programming. Minimum-order quantities apply; contact your sales representative for details and availability.
- (3) To order the adjustable version, use *TPS78101YYZ*.
- (4) The device is either fixed voltage, dual-level V_{OUT}, or adjustable voltage only. Device design does not permit a fixed and adjustable output simultaneously.

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

At T_J = −40°C to +125°C, unless otherwise noted. All voltages are with respect to GND.

PARAMETER	TPS781 Series	UNIT
Input voltage range, V _{IN}	−0.3 to +6.0	V
Enable and V _{SET} voltage range, V _{EN} and V _{VSET}	−0.3 to V _{IN} + 0.3 ⁽²⁾	V
Output voltage range, V _{OUT}	−0.3 to V _{IN} + 0.3V	V
Maximum output current, I _{OUT}	Internally limited	
Output short-circuit duration	Indefinite	
Total continuous power dissipation, P _{DISS}	See the Dissipation Ratings table	
ESD rating	Human body model (HBM)	2
	Charged device model (CDM)	500
Operating junction temperature range, T _J	−40 to +125	°C
Storage temperature range, T _{STG}	−55 to +150	°C

- (1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.
- (2) V_{EN} and V_{VSET} absolute maximum rating are V_{IN} + 0.3V or +6.0V, whichever is less.

DISSIPATION RATINGS

BOARD	PACKAGE	R _{θJC}	R _{θJA}	DERATING FACTOR ABOVE T _A = +25°C	T _A < +25°C	T _A = +70°C	T _A = +85°C
High-K ⁽¹⁾	DRV	20°C/W	65°C/W	15.4mW/°C	1540mW	845mW	615mW
High-K ⁽¹⁾	DDC	90°C/W	200°C/W	5.0mW/°C	500mW	275mW	200mW

- (1) The JEDEC high-K (2s2p) board used to derive this data was a 3-inch × 3-inch, multilayer board with 1-ounce internal power and ground planes and 2-ounce copper traces on top and bottom of the board.

ELECTRICAL CHARACTERISTICS

Over operating temperature range ($T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$), $V_{IN} = V_{OUT(NOM)} + 0.5\text{V}$ or 2.2V , whichever is greater; $I_{OUT} = 100\mu\text{A}$, $V_{VSET} = V_{EN} = V_{IN}$, $C_{OUT} = 1.0\mu\text{F}$, fixed or adjustable, unless otherwise noted. Typical values at $T_J = +25^\circ\text{C}$.

PARAMETER		TEST CONDITIONS	TPS781 Series			UNIT
			MIN	TYP	MAX	
V_{IN}	Input voltage range		2.2	5.5	5.5	V
$V_{OUT}^{(1)}$	DC output accuracy	Nominal	$T_J = +25^\circ\text{C}$, $V_{SET} = \text{high/low}$	-2	± 1	+2
		Over V_{IN} , I_{OUT} , temperature	$V_{OUT} + 0.5\text{V} \leq V_{IN} \leq 5.5\text{V}$, $0\text{mA} \leq I_{OUT} \leq 150\text{mA}$, $V_{SET} = \text{high/low}$	-3.0	± 2.0	+3.0
V_{FB}	Internal reference ⁽²⁾ (adjustable version only)		$T_J = +25^\circ\text{C}$, $V_{IN} = 4.0\text{V}$, $I_{OUT} = 75\text{mA}$	1.216		V
V_{OUT_RANGE}	Output voltage range ⁽³⁾⁽⁴⁾ (adjustable version only)		$V_{IN} = 5.5\text{V}$, $I_{OUT} = 100\mu\text{A}^{(2)}$	V_{FB}	5.25	V
$\Delta V_{OUT}/\Delta V_{IN}$	Line regulation		$V_{OUT(NOM)} + 0.5\text{V} \leq V_{IN} \leq 5.5\text{V}$, $I_{OUT} = 5\text{mA}$	-1	+1	%
$\Delta V_{OUT}/\Delta I_{OUT}$	Load regulation		$0\text{mA} \leq I_{OUT} \leq 150\text{mA}$	-2	+2	%
V_{DO}	Dropout voltage ⁽⁵⁾		$V_{IN} = 95\% V_{OUT(NOM)}$, $I_{OUT} = 150\text{mA}$		250	mV
V_N	Output noise voltage		$BW = 100\text{Hz}$ to 100kHz , $V_{IN} = 2.2\text{V}$, $V_{OUT} = 1.2\text{V}$, $I_{OUT} = 1\text{mA}$	86		μVRMS
V_{HI}	V_{SET} high (output $V_{OUT(HIGH)}$ selected), or EN high (enabled)			1.2	V_{IN}	V
V_{LO}	V_{SET} low (output $V_{OUT(HIGH)}$ selected), or EN low (disabled)			0	0.4	V
I_{CL}	Output current limit		$V_{OUT} = 0.90 \times V_{OUT(NOM)}$	150	230	400
I_{GND}	Ground pin current	$I_{OUT} = 0\text{mA}$		1.0	1.3	μA
		$I_{OUT} = 150\text{mA}$		8		μA
I_{SHDN}	Shutdown current (I_{GND})		$V_{EN} \leq 0.4\text{V}$, $2.2\text{V} \leq V_{IN} < 5.5\text{V}$, $T_J = -40^\circ\text{C}$ to $+100^\circ\text{C}$	18	130	nA
I_{VSET}	V_{SET} pin current		$V_{EN} = V_{VSET} = 5.5\text{V}$		70	nA
I_{EN}	EN pin current		$V_{EN} = V_{VSET} = 5.5\text{V}$		40	nA
I_{FB}	FB pin current ⁽⁶⁾ (adjustable version only)		$V_{IN} = 5.5\text{V}$, $V_{OUT} = 1.2\text{V}$, $I_{OUT} = 100\mu\text{A}$		10	nA
PSRR	Power-supply rejection ratio	$V_{IN} = 4.3\text{V}$, $V_{OUT} = 3.3\text{V}$, $I_{OUT} = 150\text{mA}$	$f = 10\text{Hz}$	40		dB
			$f = 100\text{Hz}$	20		dB
			$f = 1\text{kHz}$	15		dB
$t_{TR(H \rightarrow L)}$	V_{OUT} transition time (high-to-low) $V_{OUT} = 97\% \times V_{OUT(HIGH)}$	$V_{OUT_LOW} = 2.2\text{V}$, $V_{OUT(HIGH)} = 3.3\text{V}$, $I_{OUT} = 10\text{mA}$		800		μs
$t_{TR(L \rightarrow H)}$	V_{OUT} transition time (low-to-high) $V_{OUT} = 97\% \times V_{OUT(LOW)}$	$V_{OUT_HIGH} = 3.3\text{V}$, $V_{OUT(LOW)} = 2.2\text{V}$, $I_{OUT} = 10\text{mA}$		800		μs
t_{STR}	Startup time ⁽⁷⁾		$C_{OUT} = 1.0\mu\text{F}$, $V_{OUT} = 10\% V_{OUT(NOM)}$ to $V_{OUT} = 90\% V_{OUT(NOM)}$	500		μs
t_{SHDN}	Shutdown time ⁽⁸⁾		$I_{OUT} = 150\text{mA}$, $C_{OUT} = 1.0\mu\text{F}$, $V_{OUT} = 2.8\text{V}$, $V_{OUT} = 90\% V_{OUT(NOM)}$ to $V_{OUT} = 10\% V_{OUT(NOM)}$	500 ⁽⁹⁾		μs
T_{SD}	Thermal shutdown temperature	Shutdown, temperature increasing		+160		$^\circ\text{C}$
		Reset, temperature decreasing		+140		$^\circ\text{C}$
T_J	Operating junction temperature			-40	+125	$^\circ\text{C}$

(1) The output voltage for $V_{SET} = \text{low/high}$ is programmed at the factory.

(2) Adjustable version only.

(3) No V_{SET} pin on the adjustable version.

(4) No dynamic voltage scaling on the adjustable version.

(5) V_{DO} is not measured for devices with $V_{OUT(NOM)} < 2.3\text{V}$ because minimum $V_{IN} = 2.2\text{V}$.

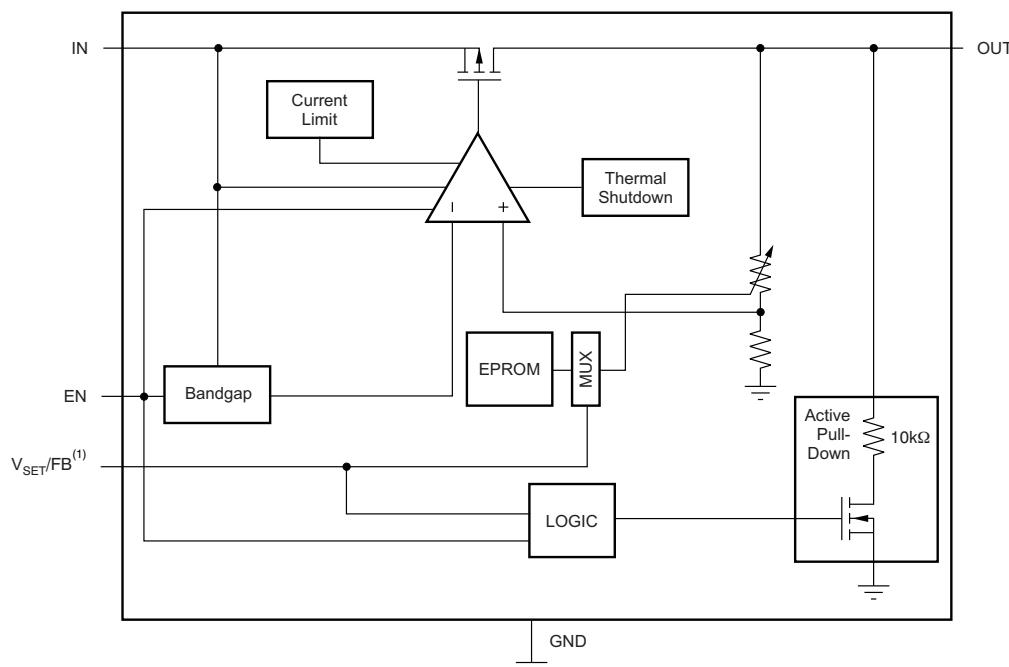
(6) The TPS78101 FB pin is tied to V_{OUT} . Adjustable version only.

(7) Time from $V_{EN} = 1.2\text{V}$ to $V_{OUT} = 90\% (V_{OUT(NOM)})$.

(8) Time from $V_{EN} = 0.4\text{V}$ to $V_{OUT} = 10\% (V_{OUT(NOM)})$.

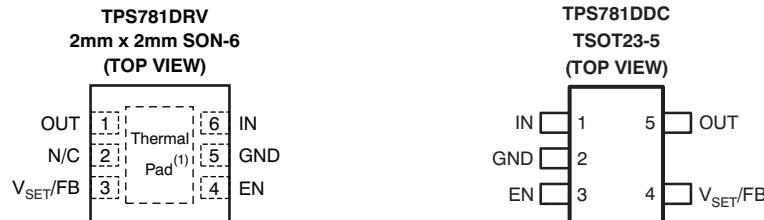
(9) See [Shutdown](#) in the [Application Information](#) section for more details.

FUNCTIONAL BLOCK DIAGRAM



(1) Feedback pin (FB) for adjustable versions; V_{SET} for fixed voltage versions.

PIN CONFIGURATIONS



(1) It is recommended that the SON package thermal pad be connected to ground.

Table 1. TERMINAL FUNCTIONS

TERMINAL			DESCRIPTION
NAME	DRV	DDC	
OUT	1	5	Regulated output voltage pin. A small (1 μ F) ceramic capacitor is needed from this pin to ground to assure stability. See the Input and Output Capacitor Requirements in the Application Information section for more details.
N/C	2	—	Not connected.
$V_{SET/FB}$	3	4	Feedback pin (FB) for adjustable versions; V_{SET} for fixed voltage versions. Driving the select pin (V_{SET}) below 0.4V selects preset output voltage high. Driving the V_{SET} pin over 1.2V selects preset output voltage low.
EN	4	3	Driving the enable pin (EN) over 1.2V turns on the regulator. Driving this pin below 0.4V puts the regulator into shutdown mode, reducing operating current to 18nA typical.
GND	5	2	Ground pin.
IN	6	1	Input pin. A small capacitor is needed from this pin to ground to assure stability. Typical input capacitor = 1.0 μ F. Both input and output capacitor grounds should be tied back to the IC ground with no significant impedance between them.
Thermal pad	Thermal pad	—	It is recommended that the SON package thermal pad be connected to ground.

TYPICAL CHARACTERISTICS

Over the operating temperature range of $T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$, $V_{IN} = V_{OUT(TYP)} + 0.5\text{V}$ or 2.2V , whichever is greater; $I_{OUT} = 100\mu\text{A}$, $V_{EN} = V_{VSET} = V_{IN}$, $C_{OUT} = 1\mu\text{F}$, and $C_{IN} = 1\mu\text{F}$, unless otherwise noted.

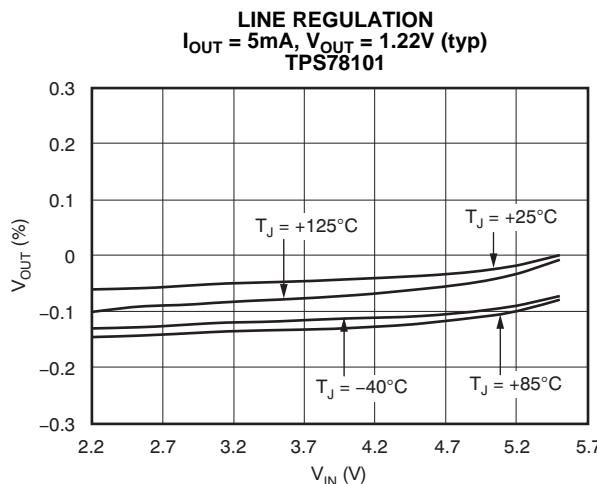


Figure 1.

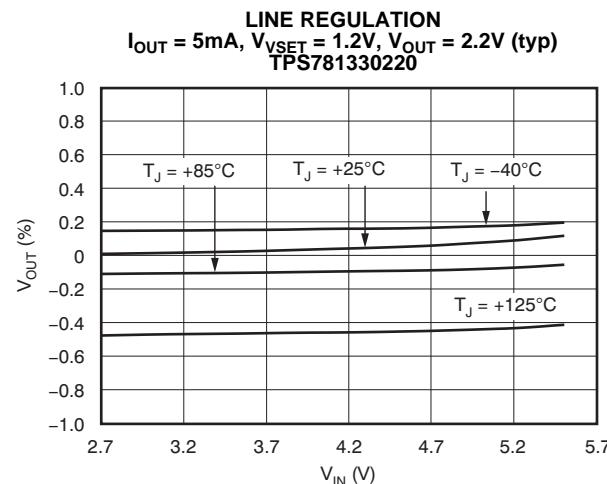


Figure 2.

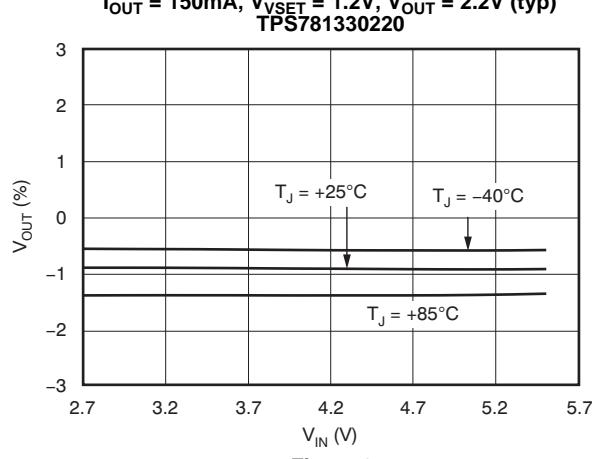


Figure 3.

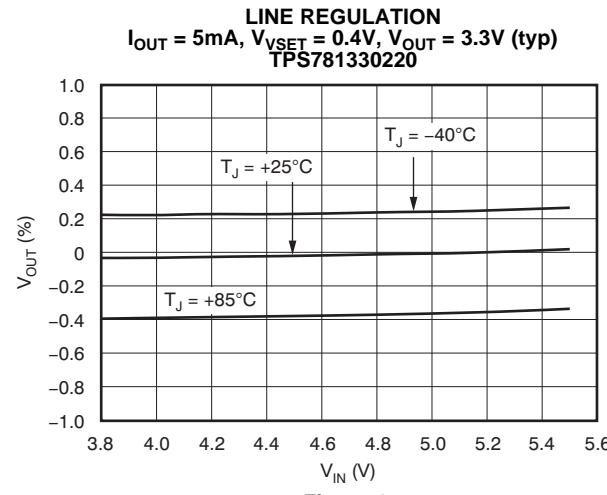


Figure 4.

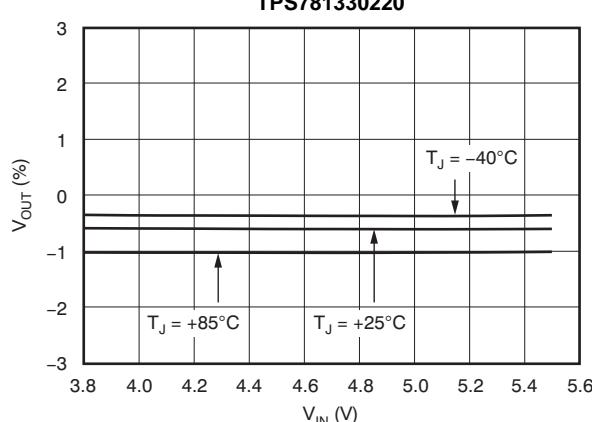


Figure 5.

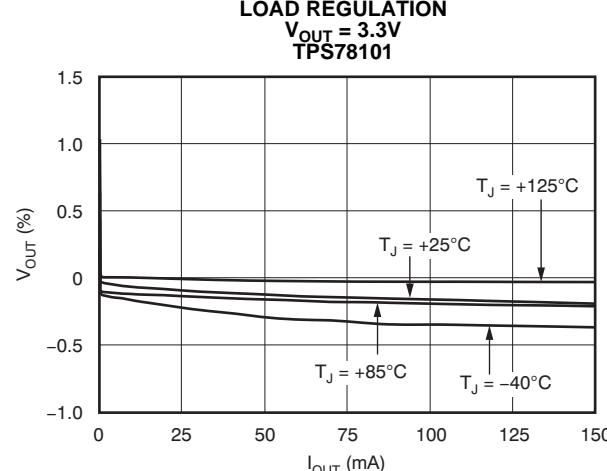


Figure 6.

TYPICAL CHARACTERISTICS (continued)

Over the operating temperature range of $T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$, $V_{IN} = V_{OUT(TYP)} + 0.5\text{V}$ or 2.2V , whichever is greater; $I_{OUT} = 100\mu\text{A}$, $V_{EN} = V_{VSET} = V_{IN}$, $C_{OUT} = 1\mu\text{F}$, and $C_{IN} = 1\mu\text{F}$, unless otherwise noted.

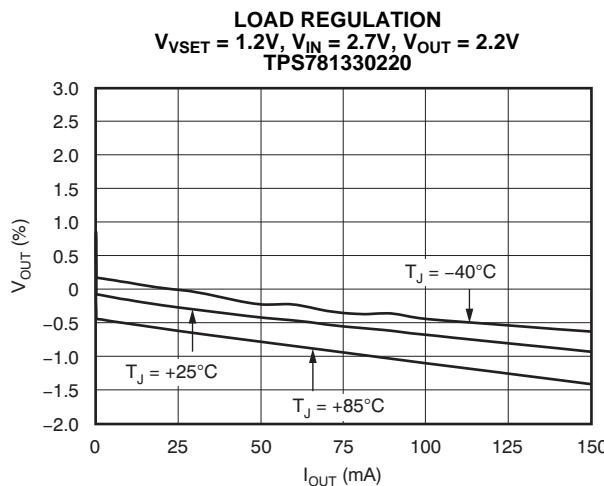


Figure 7.

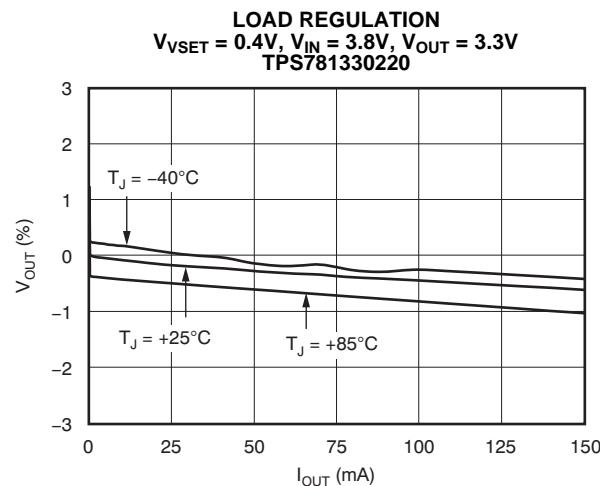


Figure 8.

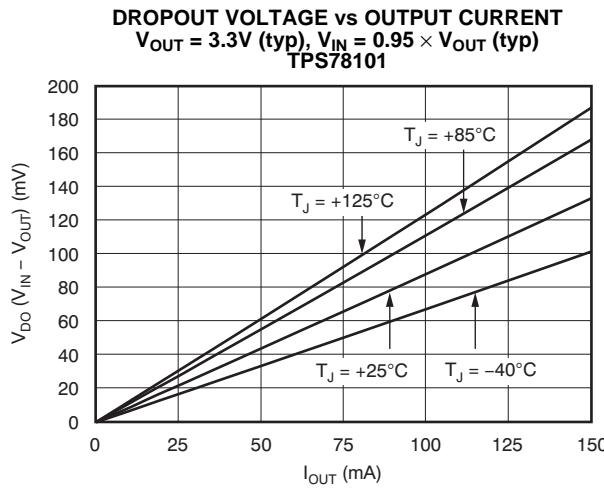


Figure 9.

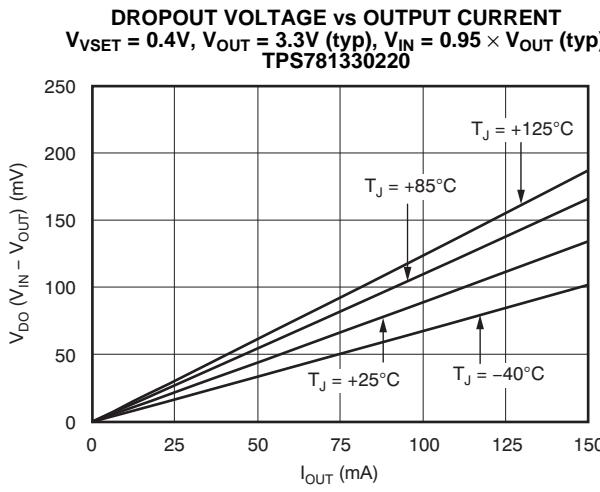


Figure 10.

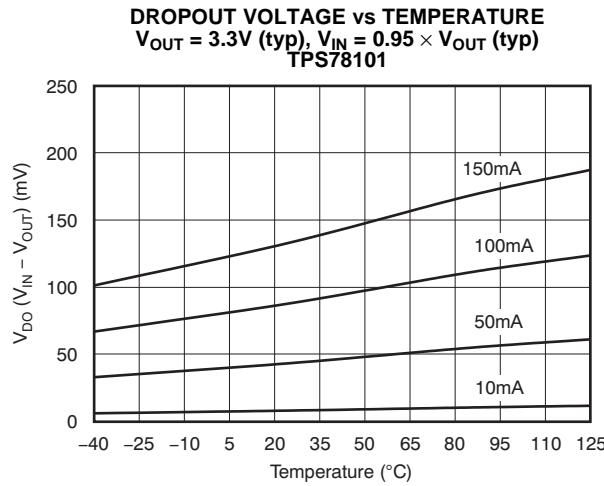


Figure 11.

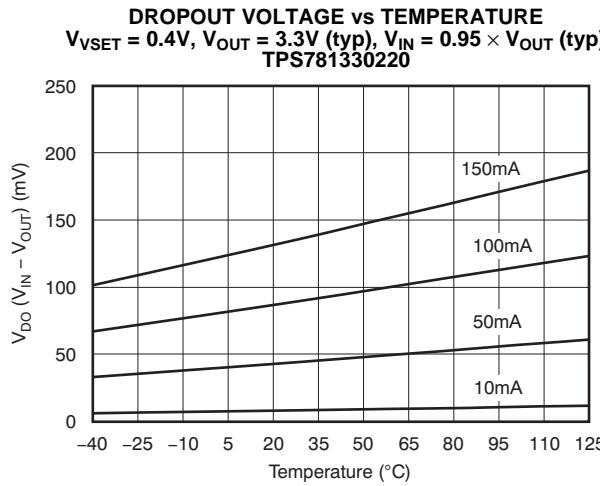


Figure 12.

TYPICAL CHARACTERISTICS (continued)

Over the operating temperature range of $T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$, $V_{IN} = V_{OUT(TYP)} + 0.5\text{V}$ or 2.2V , whichever is greater; $I_{OUT} = 100\mu\text{A}$, $V_{EN} = V_{VSET} = V_{IN}$, $C_{OUT} = 1\mu\text{F}$, and $C_{IN} = 1\mu\text{F}$, unless otherwise noted.

GROUND PIN CURRENT vs INPUT VOLTAGE
 $I_{OUT} = 50\text{mA}$, $V_{OUT} = 1.22\text{V}$
TPS78101

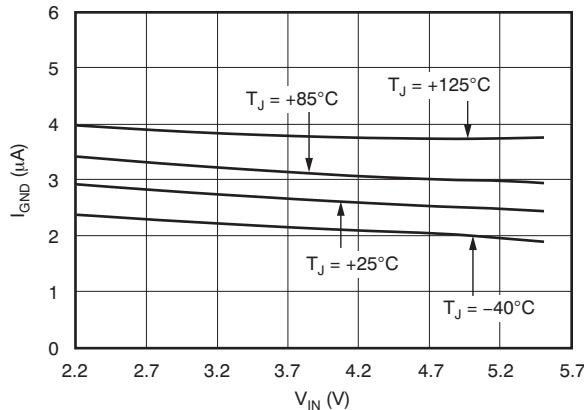


Figure 13.

GROUND PIN CURRENT vs INPUT VOLTAGE
 $I_{OUT} = 150\text{mA}$, $V_{OUT} = 1.22\text{V}$
TPS78101

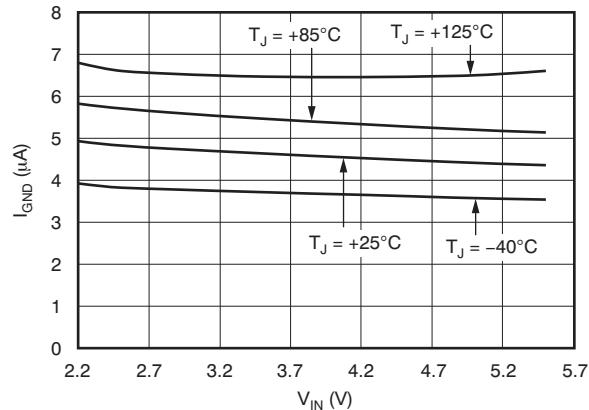


Figure 14.

GROUND PIN CURRENT vs INPUT VOLTAGE
 $I_{OUT} = 50\text{mA}$, $V_{VSET} = 1.2\text{V}$, $V_{OUT} = 2.2\text{V}$
TPS781330220

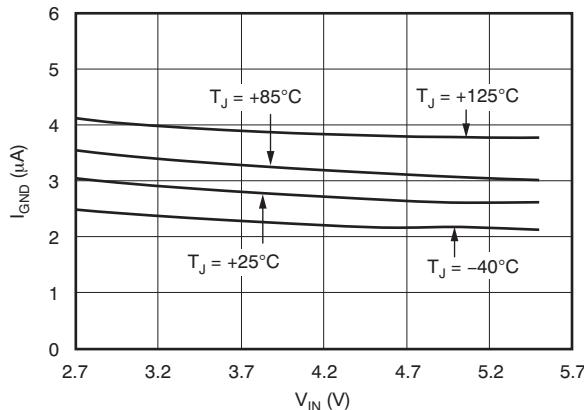


Figure 15.

GROUND PIN CURRENT vs INPUT VOLTAGE
 $I_{OUT} = 150\text{mA}$, $V_{VSET} = 1.2\text{V}$, $V_{OUT} = 2.2\text{V}$
TPS781330220

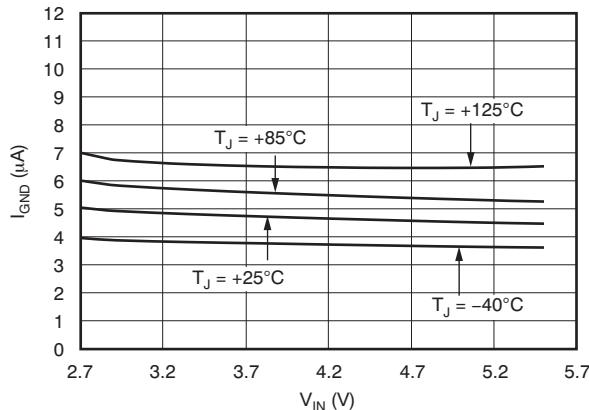


Figure 16.

GROUND PIN CURRENT vs INPUT VOLTAGE
 $I_{OUT} = 50\text{mA}$, $V_{VSET} = 0.4\text{V}$, $V_{OUT} = 3.3\text{V}$
TPS781330220

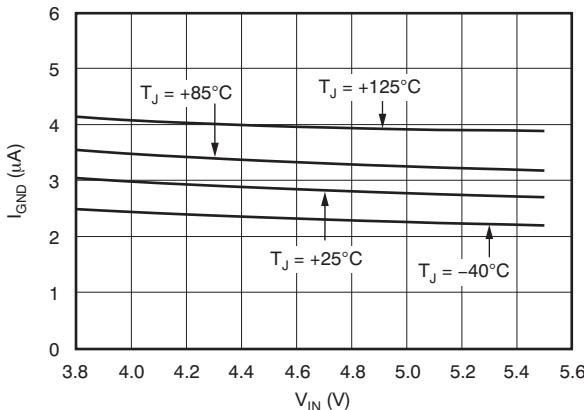


Figure 17.

GROUND PIN CURRENT vs INPUT VOLTAGE
 $I_{OUT} = 150\text{mA}$, $V_{VSET} = 0.4\text{V}$, $V_{OUT} = 3.3\text{V}$
TPS781330220

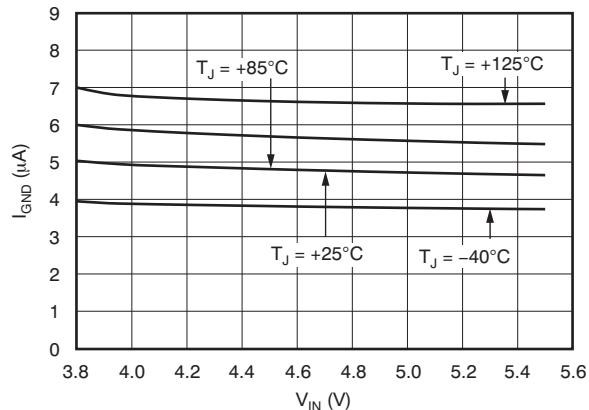


Figure 18.

TYPICAL CHARACTERISTICS (continued)

Over the operating temperature range of $T_J = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, $V_{IN} = V_{OUT(\text{typ})} + 0.5\text{V}$ or 2.2V , whichever is greater; $I_{OUT} = 100\mu\text{A}$, $V_{EN} = V_{VSET} = V_{IN}$, $C_{OUT} = 1\mu\text{F}$, and $C_{IN} = 1\mu\text{F}$, unless otherwise noted.

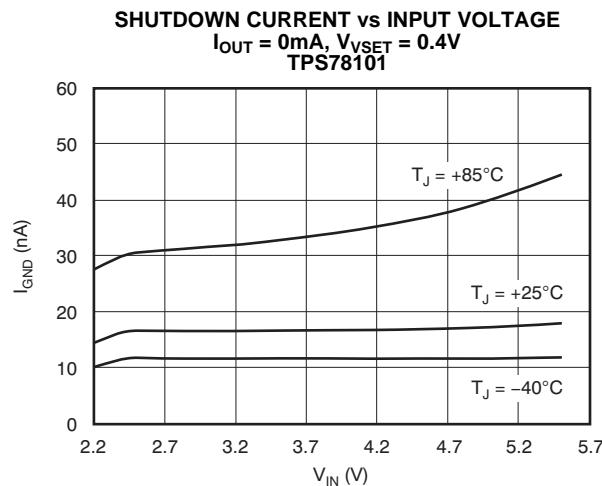


Figure 19.

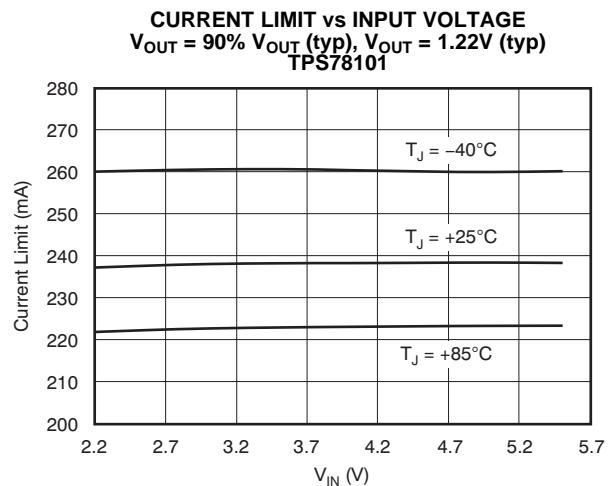


Figure 20.

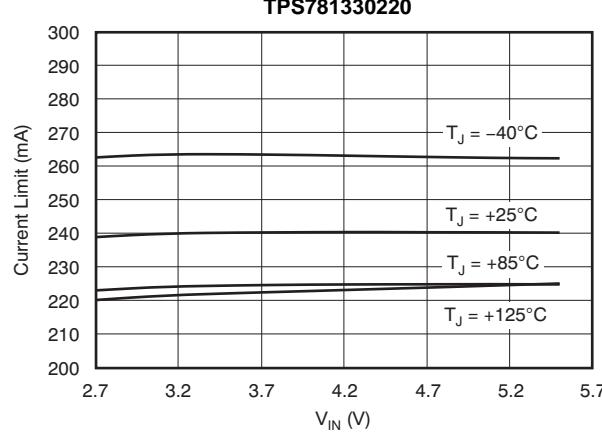


Figure 21.

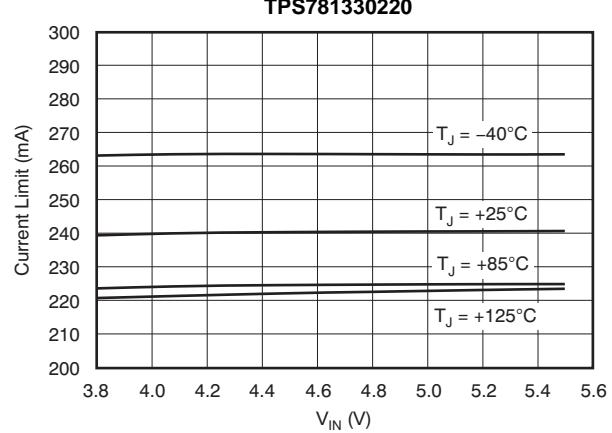


Figure 22.

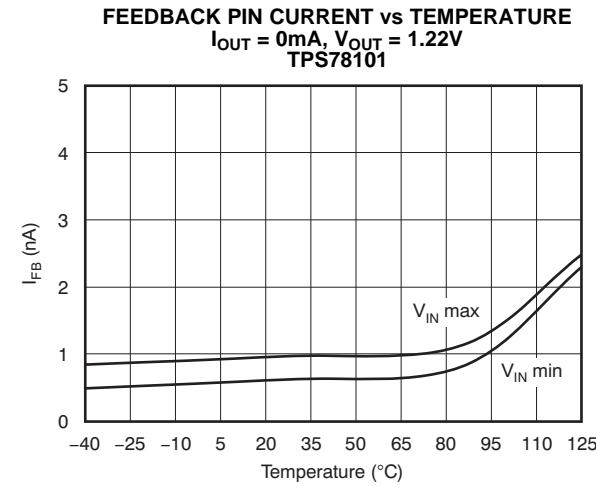


Figure 23.

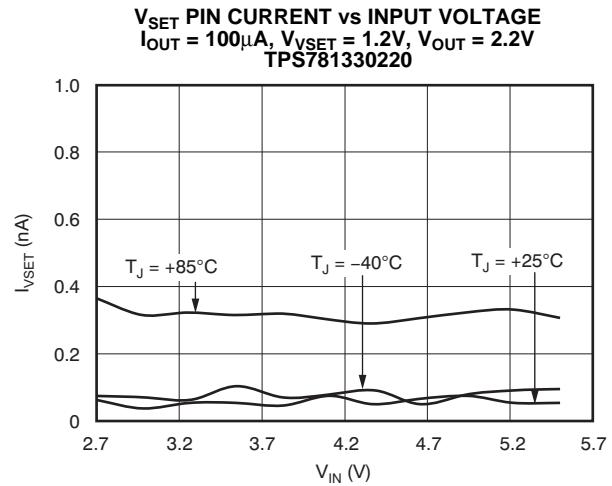


Figure 24.

TYPICAL CHARACTERISTICS (continued)

Over the operating temperature range of $T_J = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, $V_{\text{IN}} = V_{\text{OUT(TYP)}} + 0.5\text{V}$ or 2.2V , whichever is greater; $I_{\text{OUT}} = 100\mu\text{A}$, $V_{\text{EN}} = V_{\text{VSET}} = V_{\text{IN}}$, $C_{\text{OUT}} = 1\mu\text{F}$, and $C_{\text{IN}} = 1\mu\text{F}$, unless otherwise noted.

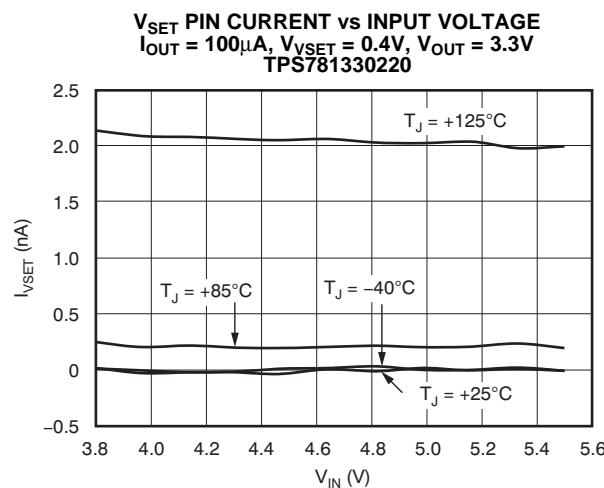


Figure 25.

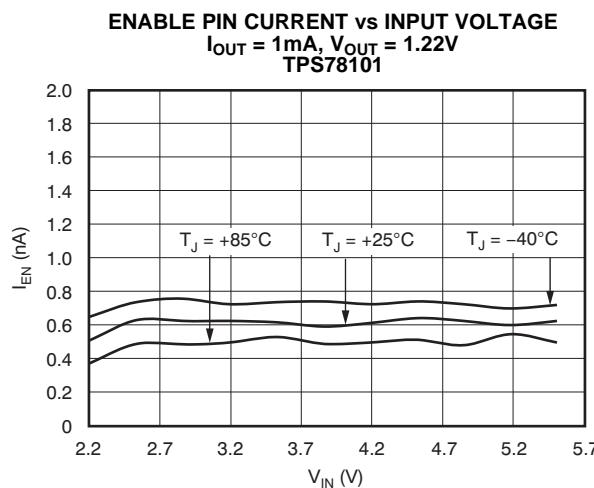


Figure 26.

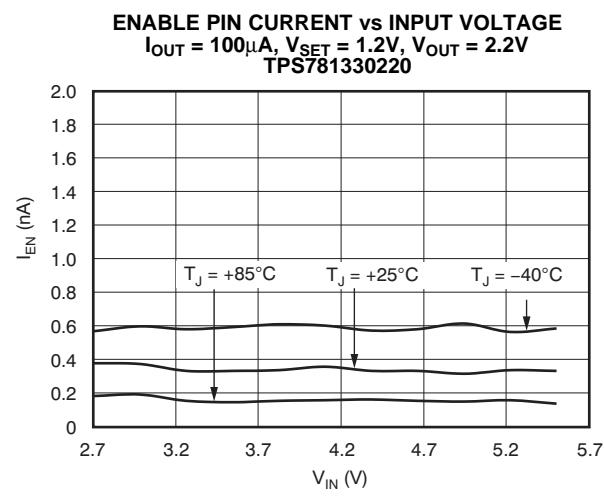


Figure 27.

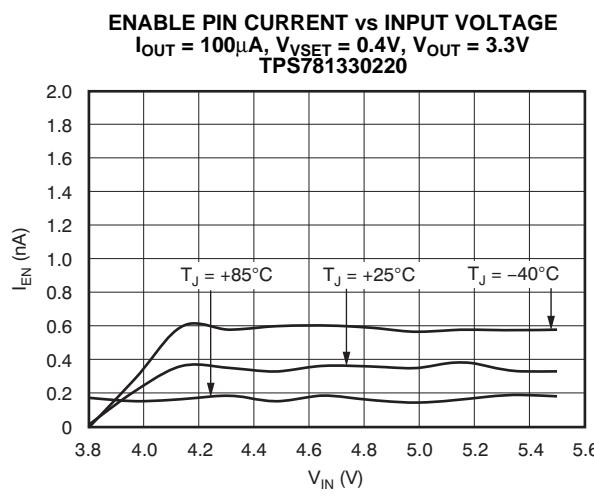


Figure 28.

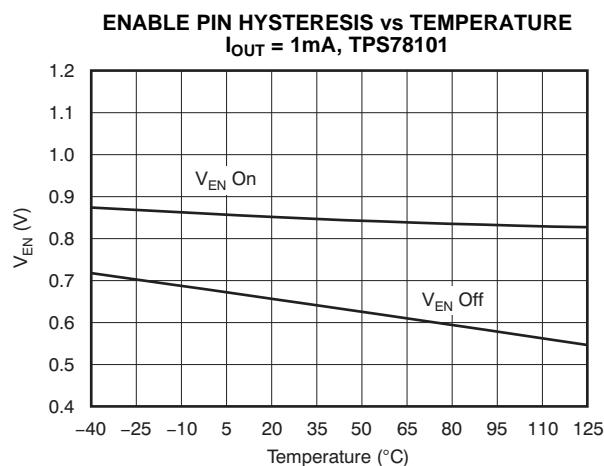


Figure 29.

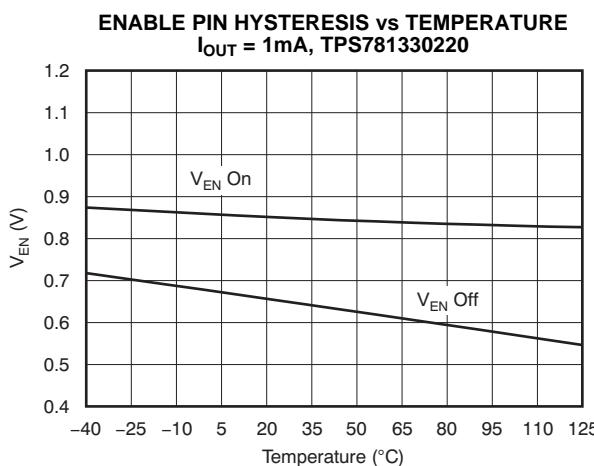


Figure 30.

TYPICAL CHARACTERISTICS (continued)

Over the operating temperature range of $T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$, $V_{\text{IN}} = V_{\text{OUT}(\text{typ})} + 0.5\text{V}$ or 2.2V , whichever is greater; $I_{\text{OUT}} = 100\mu\text{A}$, $V_{\text{EN}} = V_{\text{VSET}} = V_{\text{IN}}$, $C_{\text{OUT}} = 1\mu\text{F}$, and $C_{\text{IN}} = 1\mu\text{F}$, unless otherwise noted.

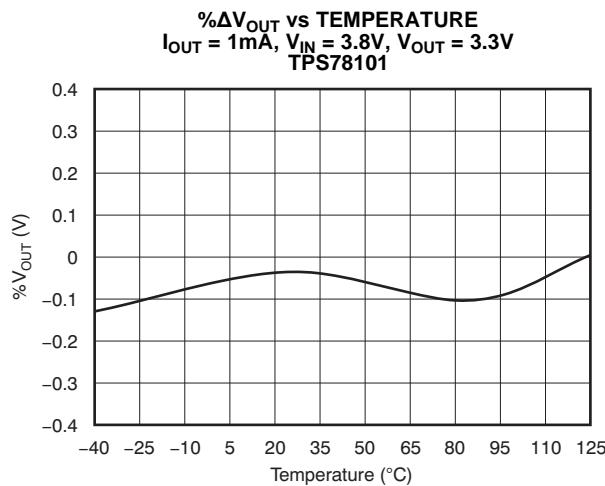


Figure 31.

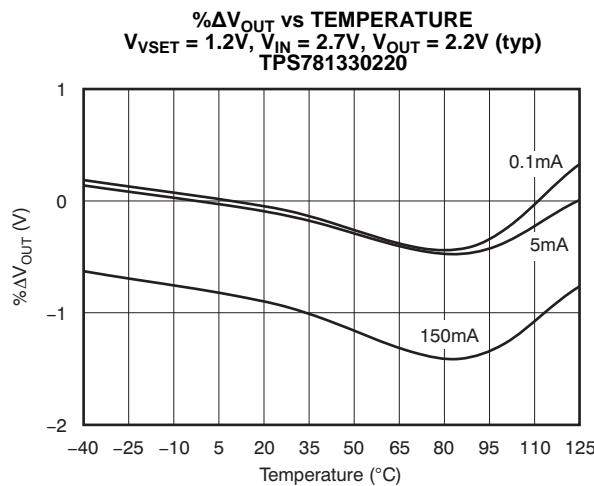


Figure 32.

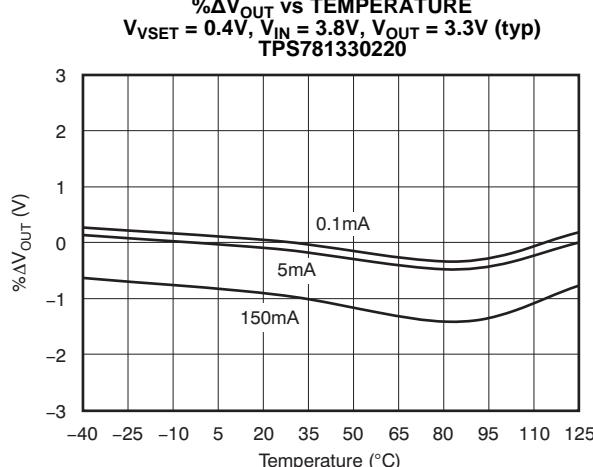


Figure 33.

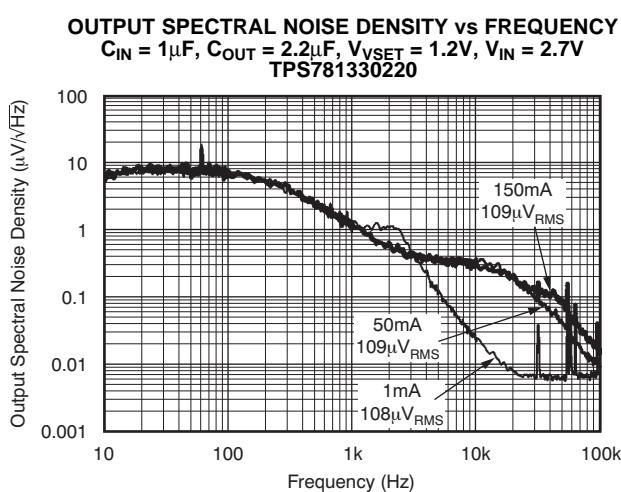


Figure 34.

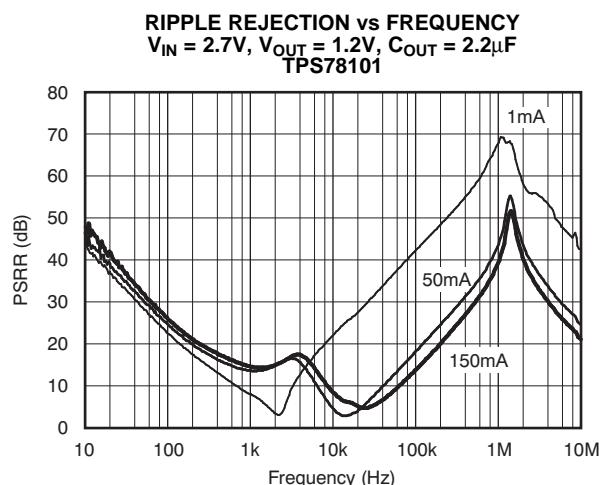


Figure 35.

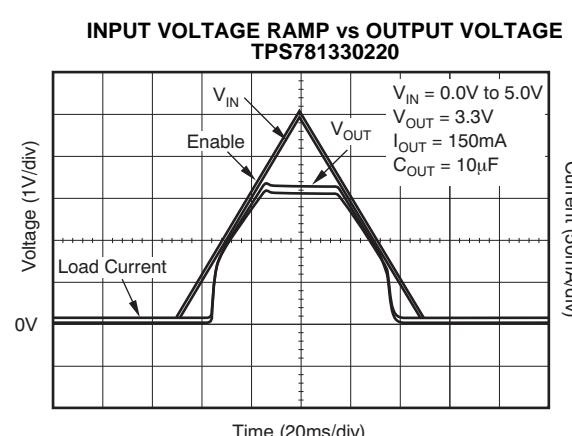


Figure 36.

TYPICAL CHARACTERISTICS (continued)

Over the operating temperature range of $T_J = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, $V_{IN} = V_{OUT(TYP)} + 0.5\text{V}$ or 2.2V , whichever is greater; $I_{OUT} = 100\mu\text{A}$, $V_{EN} = V_{VSET} = V_{IN}$, $C_{OUT} = 1\mu\text{F}$, and $C_{IN} = 1\mu\text{F}$, unless otherwise noted.

OUTPUT VOLTAGE vs ENABLE (SLOW RAMP)
TPS781330220

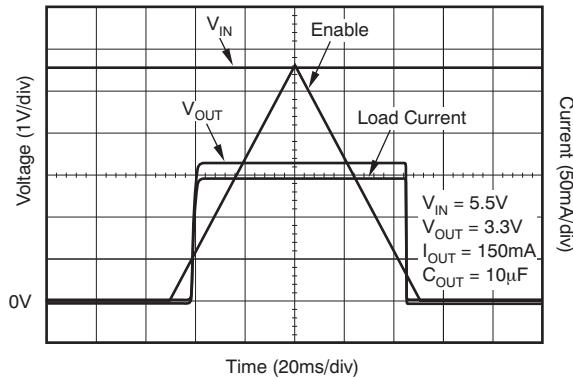


Figure 37.

INPUT VOLTAGE vs DELAY TO OUTPUT
TPS781330220

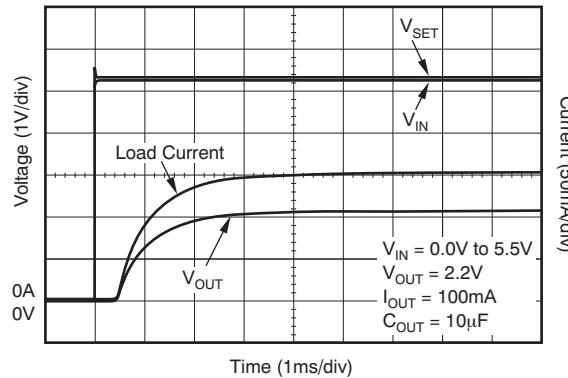


Figure 38.

LINE TRANSIENT RESPONSE
TPS781330220

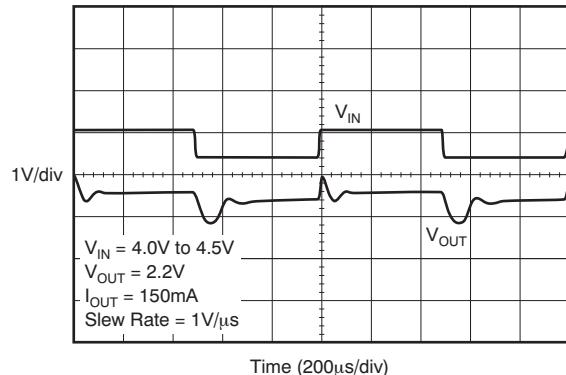


Figure 39.

LINE TRANSIENT RESPONSE
TPS781330220

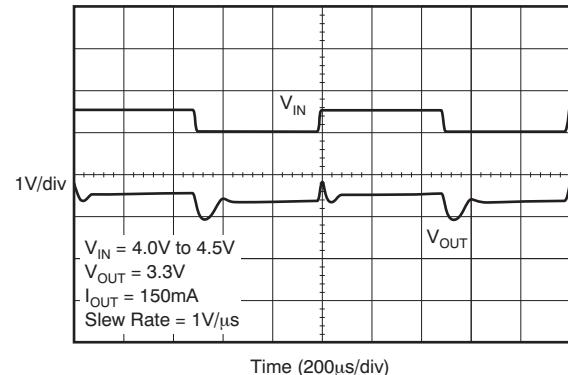


Figure 40.

LOAD TRANSIENT RESPONSE
TPS781330220

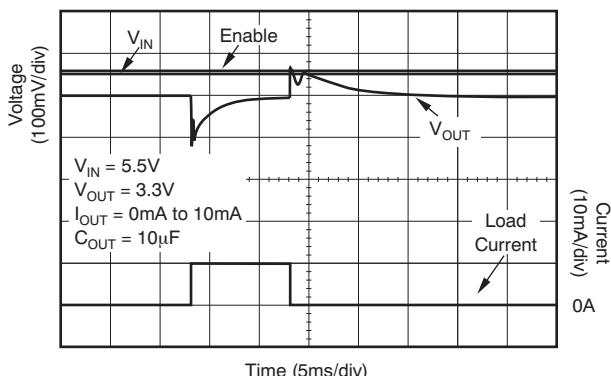


Figure 41.

LOAD TRANSIENT RESPONSE
TPS781330220

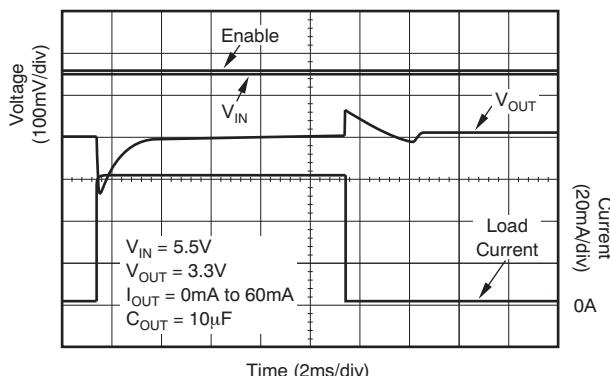


Figure 42.

TYPICAL CHARACTERISTICS (continued)

Over the operating temperature range of $T_J = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, $V_{IN} = V_{OUT(TYP)} + 0.5\text{V}$ or 2.2V , whichever is greater; $I_{OUT} = 100\mu\text{A}$, $V_{EN} = V_{VSET} = V_{IN}$, $C_{OUT} = 1\mu\text{F}$, and $C_{IN} = 1\mu\text{F}$, unless otherwise noted.

**ENABLE PIN vs OUTPUT VOLTAGE RESPONSE
AND OUTPUT CURRENT
TPS781330220**

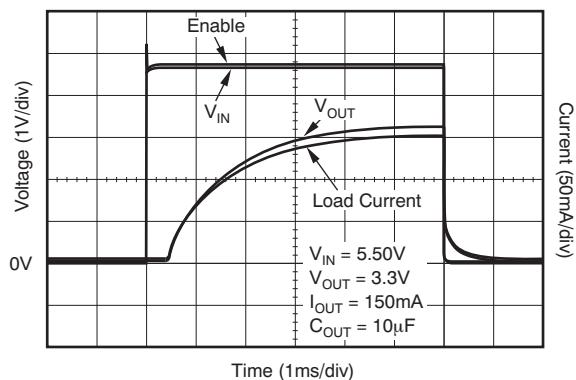


Figure 43.

**ENABLE PIN vs OUTPUT VOLTAGE DELAY
TPS781330220**

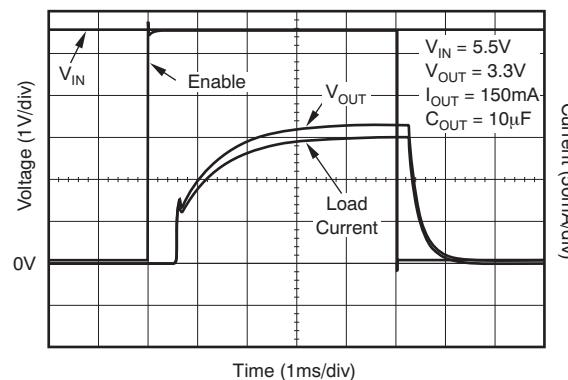


Figure 44.

**V_{SET} PIN TOGGLE
TPS781330220**

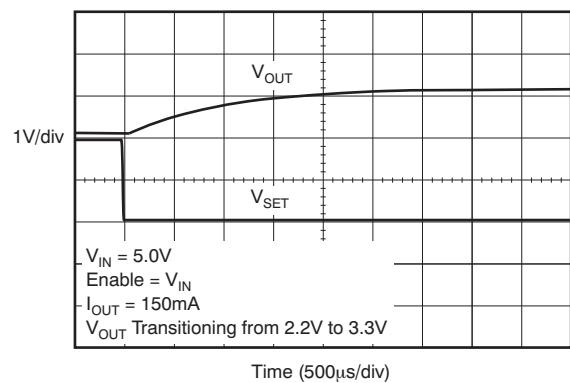


Figure 45.

**V_{SET} PIN TOGGLE
TPS781330220**

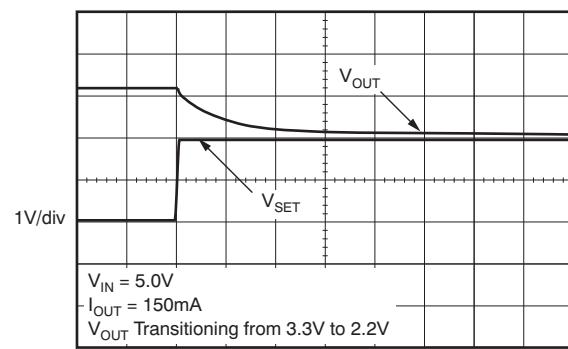


Figure 46.

**V_{SET} PIN TOGGLE (SLOW RAMP)
TPS781330220**

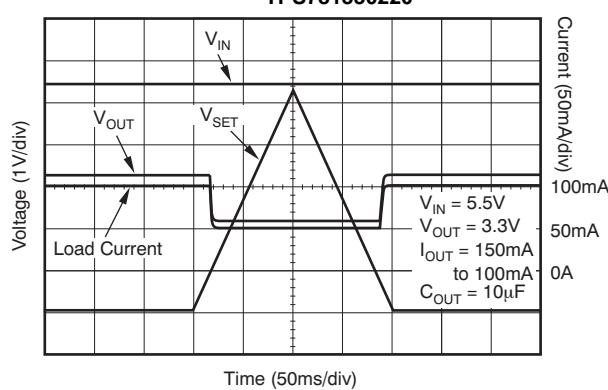


Figure 47.

APPLICATION INFORMATION

APPLICATION EXAMPLES

The TPS781 series of LDOs typically take less than 800 μ s to transition from a lower voltage of 2.2V to a higher voltage of 3.3V under an output load of 150mA; see [Figure 45](#). Additionally, the TPS781 series contain active pull-down circuitry that automatically pulls charge out of the voltage capacitor to transition the output voltage from the higher voltage to the lower voltage, even with no load connected. Output voltage overshoots and undershoots are minimal under this load condition. The TPS781 series typically take less than 800 μ s to transition from V_{SET} low (3.3V to 2.2V), or V_{SET} high (2.2V to 3.3V); see [Figure 45](#) and [Figure 46](#). Both output states of the TPS781 series are factory-programmable between 1.5V to 4.2V. Note that during startup or steady-state conditions, it is important that the EN pin and V_{SET} pin voltages never exceed $V_{IN} + 0.3V$.

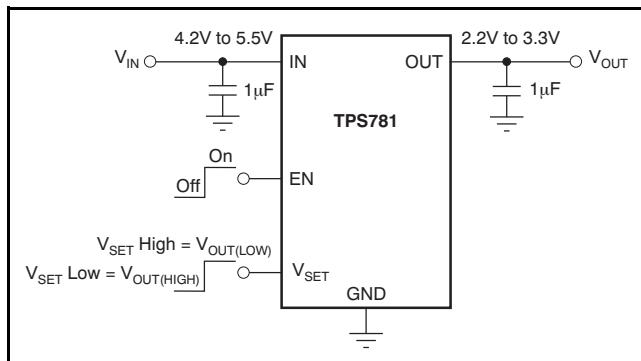


Figure 48. Typical Application Circuit

The TPS781 series is also used effectively in dynamic voltage scaling (DVS) applications. DVS applications are required to dynamically switch between a high operational voltage to a low standby voltage in order to reduce power consumption. Modern multimillion gate microprocessors fabricated with the latest sub-micron processes save power by transitioning to a lower voltage to reduce leakage currents while maintaining content. This architecture enables the microprocessor to transition quickly into an operational state (wake up) without requiring a reload of the states from external memory, or a reboot.

Programming the TPS78101 Adjustable LDO Regulator

The output voltage of the TPS78101 adjustable regulator is programmed using an external resistor divider as shown in [Figure 49](#). The output voltage operating range is 1.2V to 5.1V, and is calculated using [Equation 1](#):

$$V_{OUT} = V_{FB} \times \left(1 + \frac{R_1}{R_2}\right) \quad (1)$$

Where:

$V_{FB} = 1.216V$ typ (the internal reference voltage)

Resistors R_1 and R_2 should be chosen for approximately 1.2 μ A divider current. Lower value resistors can be used for improved noise performance, but the solution consumes more power. Higher resistor values should be avoided as leakage current into/out of FB across R_1/R_2 creates an offset voltage that artificially increases/decreases the feedback voltage and thus erroneously decreases/increases V_{OUT} . [Table 2](#) lists several common output voltages and resistor values. The recommended design procedure is to choose $R_2 = 1M\Omega$ to set the divider current at 1.2 μ A, and then calculate R_1 using [Equation 2](#):

$$R_1 = \left(\frac{V_{OUT}}{V_{FB}} - 1 \right) \times R_2 \quad (2)$$

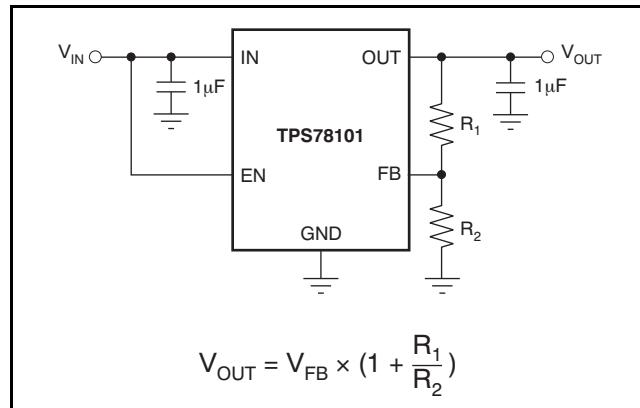


Figure 49. TPS78101 Adjustable LDO Regulator Programming

Table 2. Output Voltage Programming Guide

OUTPUT VOLTAGE	R ₁	R ₂
1.8V	0.499M Ω	1M Ω
2.8V	1.33M Ω	1M Ω
5.0V	3.16M Ω	1M Ω

Powering the MSP430 Microcontroller

Several versions of the TPS781 are ideal for powering the **MSP430** microcontroller. **Table 3** shows potential applications of some voltage versions.

Table 3. Typical MSP430 Applications

DEVICE	$V_{OUT(HIGH)}$ (TYP)	$V_{OUT(LOW)}$ (TYP)	APPLICATION
TPS781360200	3.6V	2.0V	V_{OUT} , MIN > 1.800V required by many MSP430s. Allows lowest power consumption operation.
TPS781360220	3.6V	2.2V	V_{OUT} , MIN > 2.200V required by some MSP430s FLASH operation.
TPS781360300	3.6V	3.0V	V_{OUT} , MIN > 2.700V required by some MSP430s FLASH operation.
TPS781360220	3.6V	2.2V	V_{OUT} , MIN < 3.600V required by some MSP430s. Allows highest speed operation.

The TPS781 family offers many output voltage versions to allow designers to optimize the supply voltage for the processing speed required of the MSP430. This flexible architecture minimizes the supply current consumed by the particular MSP430 application. The MSP430 total system power can be reduced by substituting the $1\mu\text{A}$ I_Q TPS781 series LDO in place of an existing, older-technology LDO. Additionally, DVS allows for increasing the clock speed in active mode (MSP430 V_{CC} = 3.6V). The 3.6V V_{CC} reduces the MSP430 time in active mode. In low-power mode, MSP430 system power can be further reduced by lowering the MSP430 V_{CC} to 2.2V in sleep mode.

Key features of the TPS781 series are an ultralow quiescent current ($1\mu\text{A}$), DVS, and miniaturized packaging. The TPS781 family are available in SON-6 and TSOT-23 packages. **Figure 50** shows a typical MSP430 circuit powered by an LDO without DVS. **Figure 51** is an MSP430 circuit using a TPS781 LDO that incorporates an integrated DVS, thus simplifying the circuit design. In a circuit without DVS, as **Figure 50** illustrates, V_{CC} is always at 3.0V. When the MSP430 goes into sleep mode, V_{CC} remains at 3.0V; if DVS is applied, V_{CC} could be reduced in sleep mode. In **Figure 51**, the TPS781 LDO with integrated DVS maintains 3.6V V_{CC} until a logic high signal from the MSP430 forces V_{OUT} to level shift V_{OUT} from 3.6V down to 2.2V; thus reducing power in sleep mode.

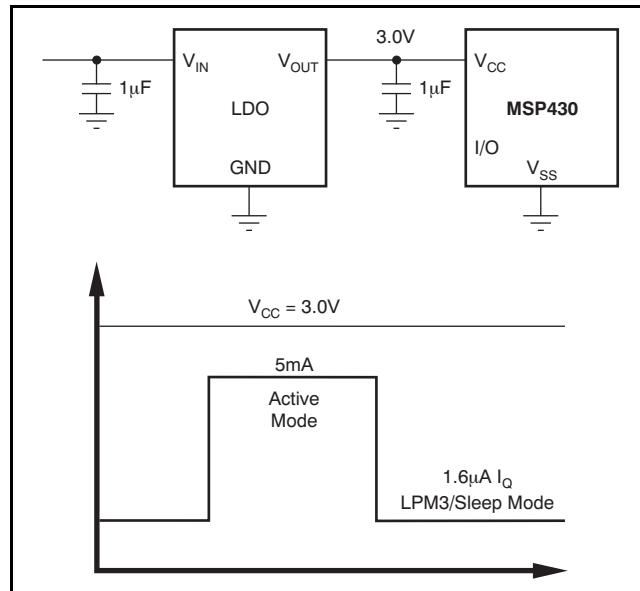


Figure 50. Typical LDO without DVS

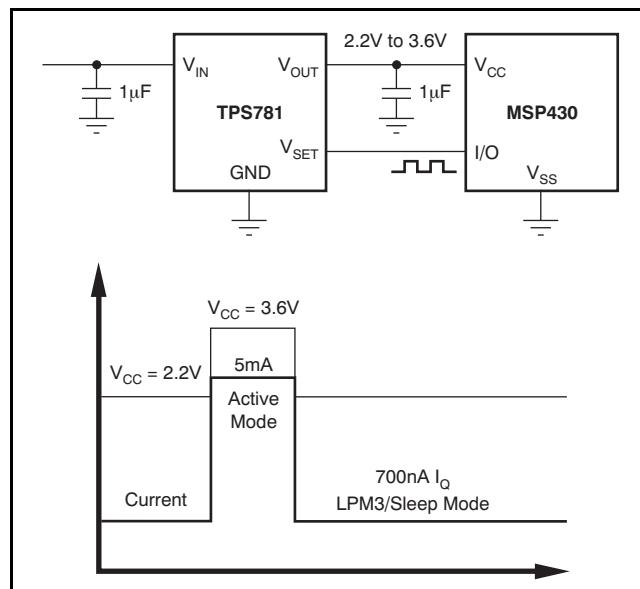


Figure 51. TPS781 with Integrated DVS

The other benefit of DVS is that it allows a higher V_{CC} voltage on the MSP430, increasing the clock speed and reducing the active mode dwell time.

INPUT AND OUTPUT CAPACITOR REQUIREMENTS

Although an input capacitor is not required for stability, it is good analog design practice to connect a $0.1\mu\text{F}$ to $1.0\mu\text{F}$ low equivalent series resistance (ESR) capacitor across the input supply near the regulator. This capacitor counteracts reactive input sources and improves transient response, noise rejection, and ripple rejection. A higher-value capacitor may be necessary if large, fast rise-time load transients are anticipated, or if the device is not located near the power source. If source impedance is not sufficiently low, a $0.1\mu\text{F}$ input capacitor may be necessary to ensure stability.

The TPS781 series are designed to be stable with standard ceramic capacitors with values of $1.0\mu\text{F}$ or larger at the output. X5R- and X7R-type capacitors are best because they have minimal variation in value and ESR over temperature. Maximum ESR should be less than 1.0Ω . With tolerance and dc bias effects, the minimum capacitance to ensure stability is $1\mu\text{F}$.

BOARD LAYOUT RECOMMENDATIONS TO IMPROVE PSRR AND NOISE PERFORMANCE

To improve ac performance (such as PSRR, output noise, and transient response), it is recommended that the printed circuit board (PCB) be designed with separate ground planes for V_{IN} and V_{OUT} , with each ground plane connected only at the GND pin of the device. In addition, the ground connection for the output capacitor should connect directly to the GND pin of the device. High ESR capacitors may degrade PSRR.

INTERNAL CURRENT LIMIT

The TPS781 is internally current-limited to protect the regulator during fault conditions. During current limit, the output sources a fixed amount of current that is largely independent of output voltage. For reliable operation, the device should not be operated in a current limit state for extended periods of time.

The PMOS pass element in the TPS781 series has a built-in body diode that conducts current when the voltage at OUT exceeds the voltage at IN. This current is not limited, so if extended reverse voltage operation is anticipated, external limiting to 5% of rated output current may be appropriate.

SHUTDOWN

The enable pin (EN) is active high and is compatible with standard and low-voltage CMOS levels. When shutdown capability is not required, EN should be connected to the IN pin, as shown in Figure 52. Figure 53 shows both EN and V_{SET} connected to IN. The TPS781 series, with internal active output pull-down circuitry, discharges the output to within 5% V_{OUT} with a time (t) shown in Equation 3:

$$t = 3 \left(\frac{10\text{k}\Omega \times R_L}{10\text{k}\Omega + R_L} \right) \times C_{OUT} \quad (3)$$

Where:

R_L = output load resistance

C_{OUT} = output capacitance

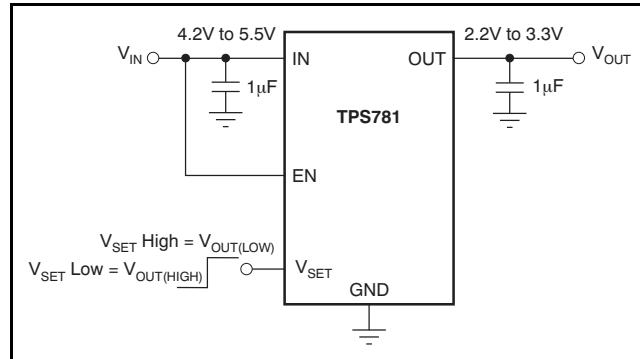


Figure 52. Circuit Showing EN Tied High when Shutdown Capability is Not Required

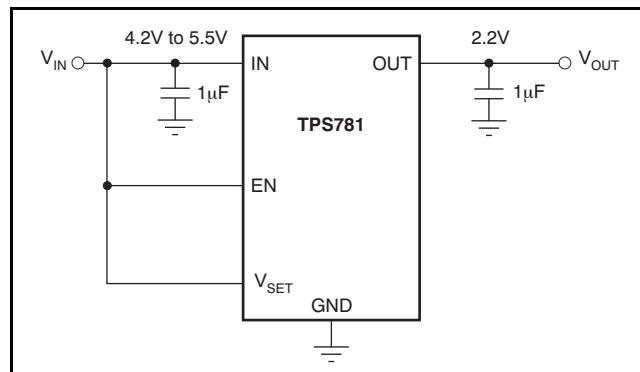


Figure 53. Circuit to Tie Both EN and V_{SET} High

DROPOUT VOLTAGE

The TPS781 series use a PMOS pass transistor to achieve low dropout. When $(V_{IN} - V_{OUT})$ is less than the dropout voltage (V_{DO}), the PMOS pass device is in the linear region of operation and the input-to-output resistance is the $R_{DS(ON)}$ of the PMOS pass element. V_{DO} approximately scales with output current because the PMOS device behaves like a resistor in dropout. As with any linear regulator, PSRR and transient response are degraded as $(V_{IN} - V_{OUT})$ approaches dropout. This effect is shown in the Typical Characteristics section. Refer to application report [SLVA207, Understanding LDO Dropout](#), available for download from www.ti.com.

TRANSIENT RESPONSE

As with any regulator, increasing the size of the output capacitor reduces over/undershoot magnitude but increases duration of the transient response. For more information, see [Figure 42](#).

ACTIVE V_{OUT} PULL-DOWN

In the TPS781 series, the active pull-down discharges V_{OUT} when the device is off. However, the input voltage must be greater than 2.2V for the active pull-down to work.

MINIMUM LOAD

The TPS781 series are stable with no output load. Traditional PMOS LDO regulators suffer from lower loop gain at very light output loads. The TPS781 employs an innovative, low-current circuit under very light or no-load conditions, resulting in improved output voltage regulation performance down to zero output current. See [Figure 41](#) for the load transient response.

Thermal Information

Thermal Protection

Thermal protection disables the output when the junction temperature rises to approximately $+160^{\circ}\text{C}$, allowing the device to cool. Once the junction temperature cools to approximately $+140^{\circ}\text{C}$, the output circuitry is enabled. Depending on power dissipation, thermal resistance, and ambient temperature, the thermal protection circuit may cycle on and off again. This cycling limits the dissipation of the regulator, protecting it from damage as a result of overheating.

Any tendency to activate the thermal protection circuit indicates excessive power dissipation or an inadequate heatsink. For reliable operation, junction temperature should be limited to $+125^{\circ}\text{C}$ maximum. To estimate the margin of safety in a complete design (including heatsink), increase the ambient temperature until the thermal protection is triggered; use worst-case loads and signal conditions. For good reliability, thermal protection should trigger at least $+35^{\circ}\text{C}$ above the maximum expected ambient condition of your particular application. This configuration produces a worst-case junction temperature of $+125^{\circ}\text{C}$ at the highest expected ambient temperature and worst-case load.

The internal protection circuitry of the TPS781 series has been designed to protect against overload conditions. However, it is not intended to replace proper heatsinking. Continuously running the TPS781 series into thermal shutdown degrades device reliability.

Power Dissipation

The ability to remove heat from the die is different for each package type, presenting different considerations in the PCB layout. The PCB area around the device that is free of other components moves the heat from the device to the ambient air. Performance data for JEDEC low- and high-K boards are given in the [Dissipation Ratings](#) table. Using heavier copper increases the effectiveness in removing heat from the device. The addition of plated through-holes to heat-dissipating layers also improves the heatsink effectiveness. Power dissipation depends on input voltage and load conditions. Power dissipation (P_D) is equal to the product of the output current times the voltage drop across the output pass element (V_{IN} to V_{OUT}), as shown in [Equation 4](#):

$$P_D = (V_{IN} - V_{OUT}) \times I_{OUT} \quad (4)$$

Package Mounting

Solder pad footprint recommendations for the TPS781 series are available from the Texas Instruments web site at www.ti.com through the [TPS781 series product folders](#).

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS78101DDCR	Active	Production	SOT-23-THIN (DDC) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	CEB
TPS78101DDCR.A	Active	Production	SOT-23-THIN (DDC) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	CEB
TPS78101DDCRG4	Active	Production	SOT-23-THIN (DDC) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	CEB
TPS78101DDCRG4.A	Active	Production	SOT-23-THIN (DDC) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	CEB
TPS78101DDCT	Active	Production	SOT-23-THIN (DDC) 5	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	CEB
TPS78101DDCT.A	Active	Production	SOT-23-THIN (DDC) 5	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	CEB
TPS78101DRV	Active	Production	WSON (DRV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CEB
TPS78101DRV.A	Active	Production	WSON (DRV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CEB
TPS78101DRVRG4	Active	Production	WSON (DRV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CEB
TPS78101DRVRG4.A	Active	Production	WSON (DRV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CEB
TPS78101DRV	Active	Production	WSON (DRV) 6	250 SMALL T&R	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	CEB
TPS78101DRV.T	Active	Production	WSON (DRV) 6	250 SMALL T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	CEB
TPS781250200DDCR	Active	Production	SOT-23-THIN (DDC) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SAN
TPS781250200DDCR.A	Active	Production	SOT-23-THIN (DDC) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SAN
TPS781250200DDCT	Active	Production	SOT-23-THIN (DDC) 5	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SAN
TPS781250200DDCT.A	Active	Production	SOT-23-THIN (DDC) 5	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SAN
TPS781330220DDCR	Active	Production	SOT-23-THIN (DDC) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	CED
TPS781330220DDCR.A	Active	Production	SOT-23-THIN (DDC) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	CED
TPS781330220DDCT	Active	Production	SOT-23-THIN (DDC) 5	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	CED

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS781330220DDCT.A	Active	Production	SOT-23- THIN (DDC) 5	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	CED
TPS781330220DRV.R	Active	Production	WSON (DRV) 6	3000 LARGE T&R	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	CED
TPS781330220DRV.R.A	Active	Production	WSON (DRV) 6	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	CED
TPS781330220DRV.T	Active	Production	WSON (DRV) 6	250 SMALL T&R	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	CED
TPS781330220DRV.T.A	Active	Production	WSON (DRV) 6	250 SMALL T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	CED

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

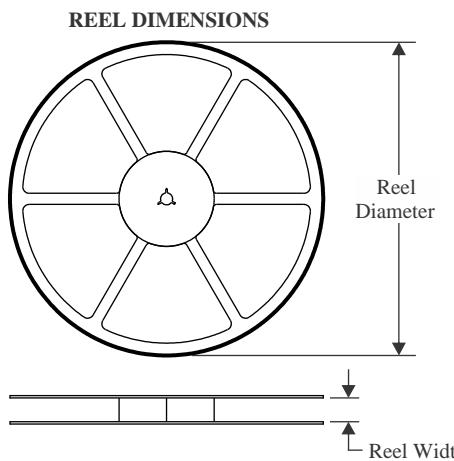
⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

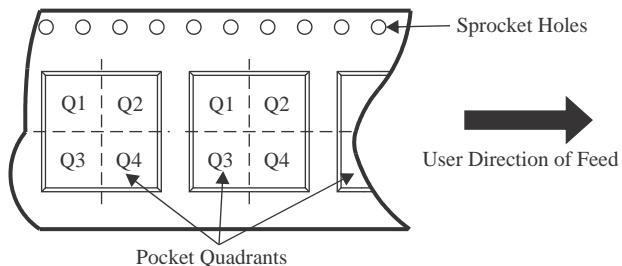
Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION


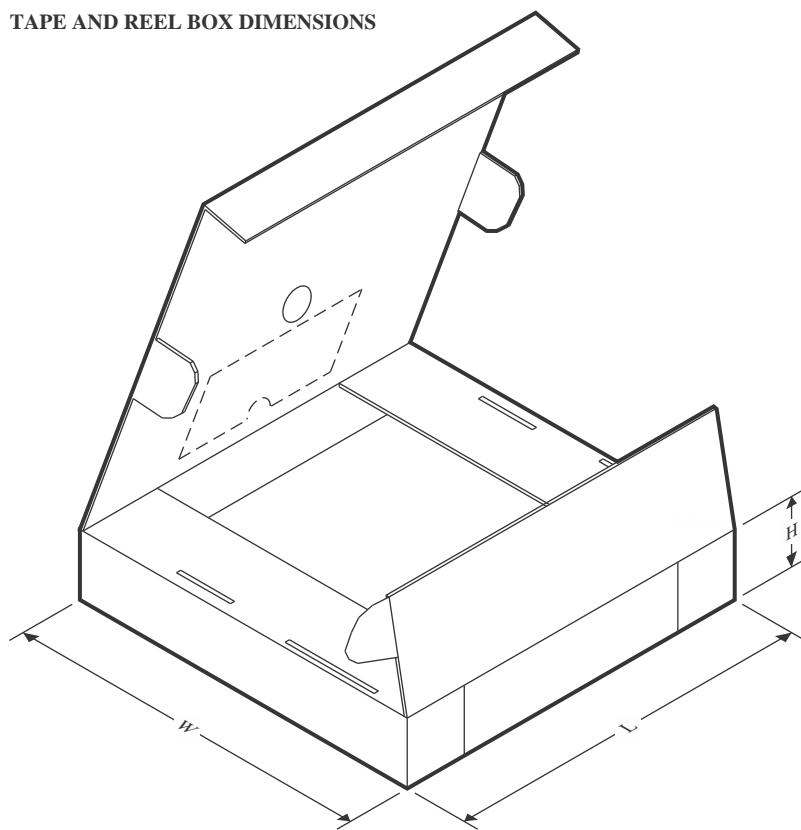
A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS78101DDCR	SOT-23-THIN	DDC	5	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS78101DDCRG4	SOT-23-THIN	DDC	5	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS78101DDCT	SOT-23-THIN	DDC	5	250	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS78101DRV	WSON	DRV	6	3000	178.0	8.4	2.25	2.25	1.0	4.0	8.0	Q2
TPS78101DRVG4	WSON	DRV	6	3000	178.0	8.4	2.25	2.25	1.0	4.0	8.0	Q2
TPS78101DRV	WSON	DRV	6	250	178.0	8.4	2.25	2.25	1.0	4.0	8.0	Q2
TPS78101DRV	WSON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS781250200DDCR	SOT-23-THIN	DDC	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS781250200DDCT	SOT-23-THIN	DDC	5	250	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS781330220DDCR	SOT-23-THIN	DDC	5	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS781330220DDCT	SOT-23-THIN	DDC	5	250	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS781330220DRV	WSON	DRV	6	3000	178.0	8.4	2.25	2.25	1.0	4.0	8.0	Q2
TPS781330220DRV	WSON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS781330220DRV	WSON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS781330220DRV	WSON	DRV	6	250	178.0	8.4	2.25	2.25	1.0	4.0	8.0	Q2

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS78101DDCR	SOT-23-THIN	DDC	5	3000	213.0	191.0	35.0
TPS78101DDCRG4	SOT-23-THIN	DDC	5	3000	213.0	191.0	35.0
TPS78101DDCT	SOT-23-THIN	DDC	5	250	213.0	191.0	35.0
TPS78101DRV	WSON	DRV	6	3000	205.0	200.0	33.0
TPS78101DRVRG4	WSON	DRV	6	3000	205.0	200.0	33.0
TPS78101DRV	WSON	DRV	6	250	205.0	200.0	33.0
TPS78101DRV	WSON	DRV	6	250	203.0	203.0	35.0
TPS781250200DDCR	SOT-23-THIN	DDC	5	3000	213.0	191.0	35.0
TPS781250200DDCT	SOT-23-THIN	DDC	5	250	213.0	191.0	35.0
TPS781330220DDCR	SOT-23-THIN	DDC	5	3000	213.0	191.0	35.0
TPS781330220DDCT	SOT-23-THIN	DDC	5	250	213.0	191.0	35.0
TPS781330220DRV	WSON	DRV	6	3000	205.0	200.0	33.0
TPS781330220DRV	WSON	DRV	6	3000	203.0	203.0	35.0
TPS781330220DRV	WSON	DRV	6	250	200.0	183.0	25.0
TPS781330220DRV	WSON	DRV	6	250	205.0	200.0	33.0

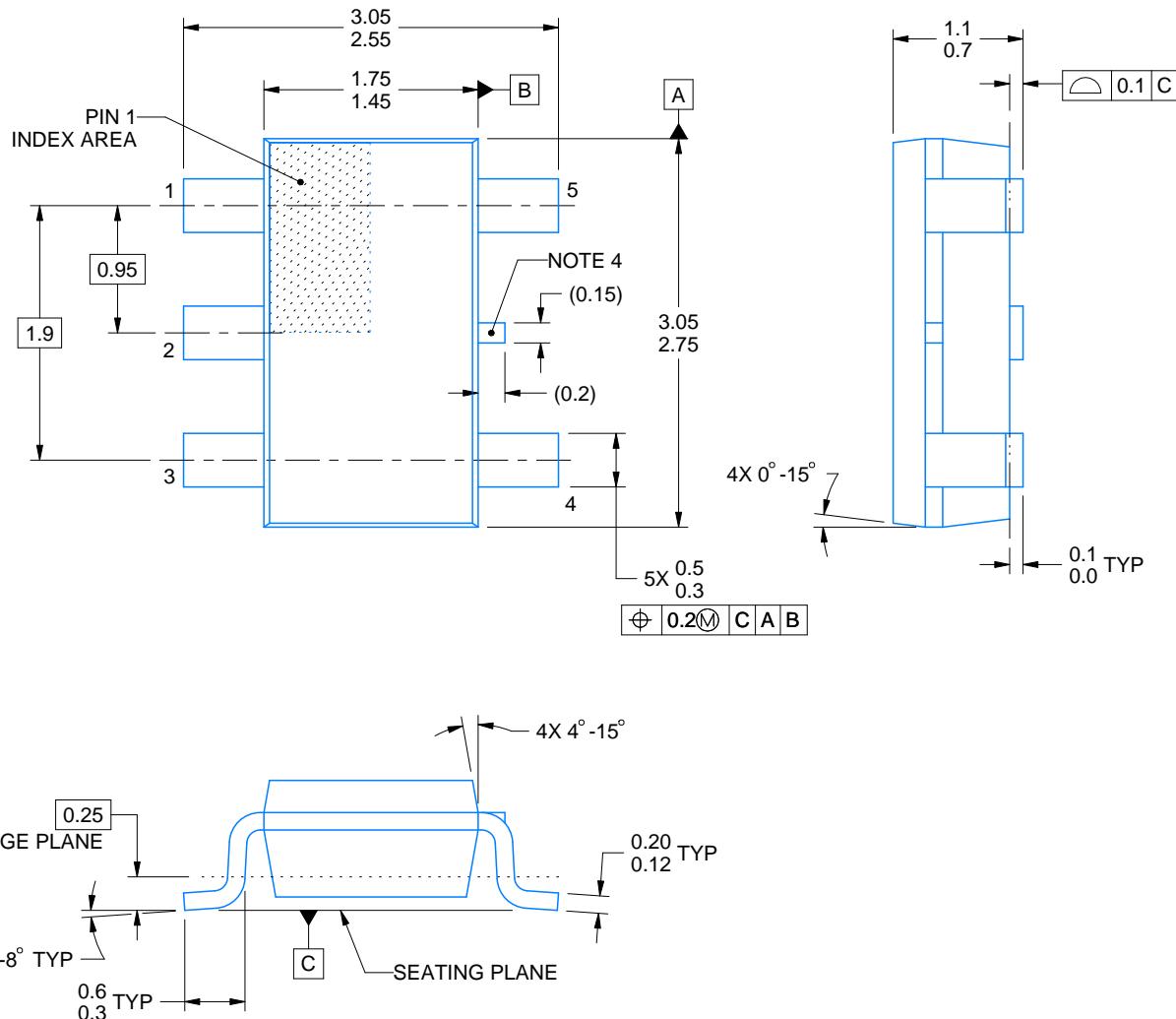
PACKAGE OUTLINE

DDC0005A



SOT-23 - 1.1 max height

SMALL OUTLINE TRANSISTOR



4220752/C 08/2024

NOTES:

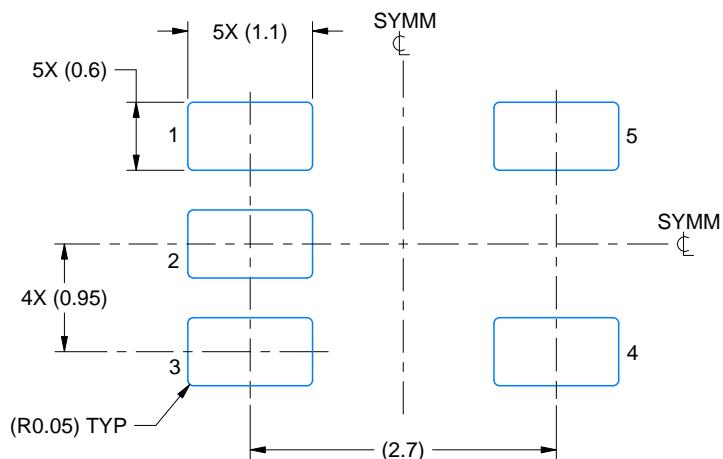
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-193.
4. Support pin may differ or may not be present.

EXAMPLE BOARD LAYOUT

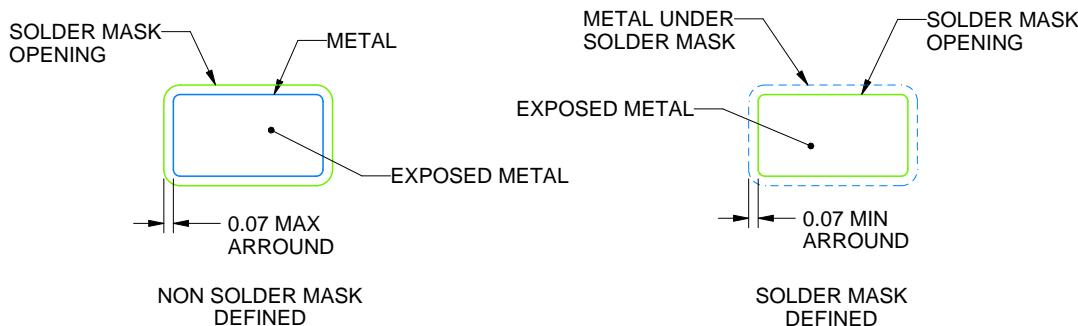
DDC0005A

SOT-23 - 1.1 max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPLODED METAL SHOWN
SCALE:15X



SOLDERMASK DETAILS

4220752/C 08/2024

NOTES: (continued)

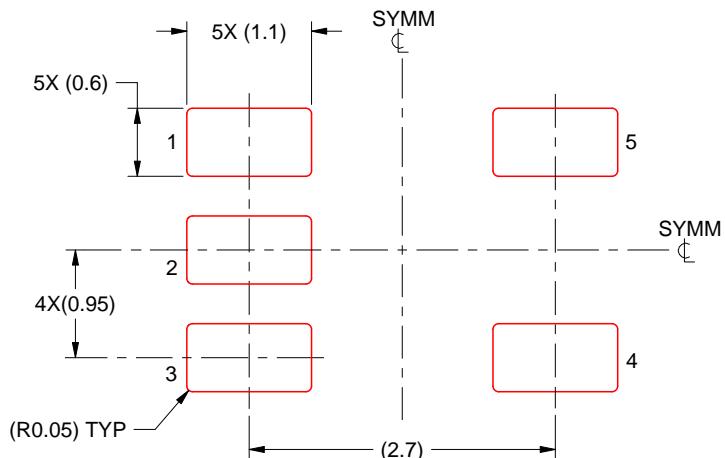
4. Publication IPC-7351 may have alternate designs.
5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DDC0005A

SOT-23 - 1.1 max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:15X

4220752/C 08/2024

NOTES: (continued)

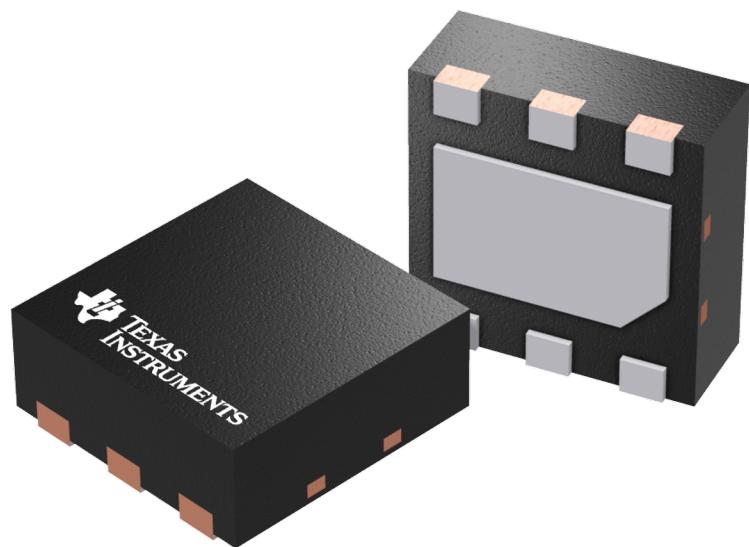
6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
7. Board assembly site may have different recommendations for stencil design.

DRV 6

GENERIC PACKAGE VIEW

WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD

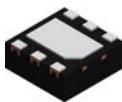


Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4206925/F

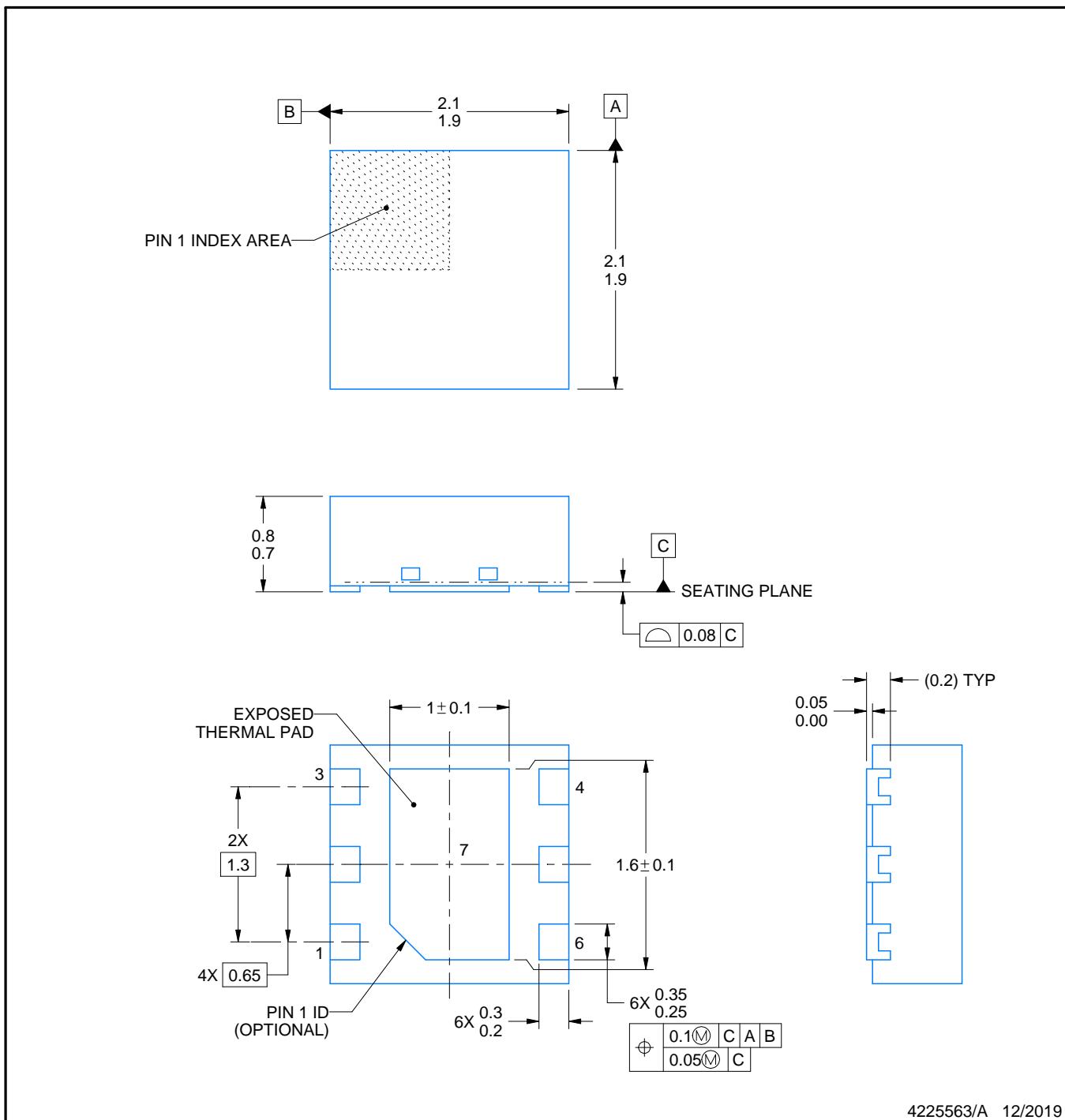
PACKAGE OUTLINE

DRV0006D



WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



4225563/A 12/2019

NOTES:

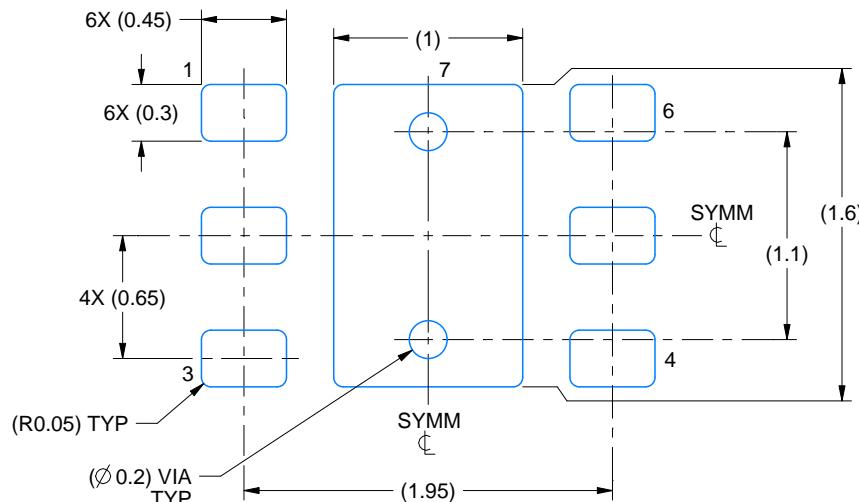
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

EXAMPLE BOARD LAYOUT

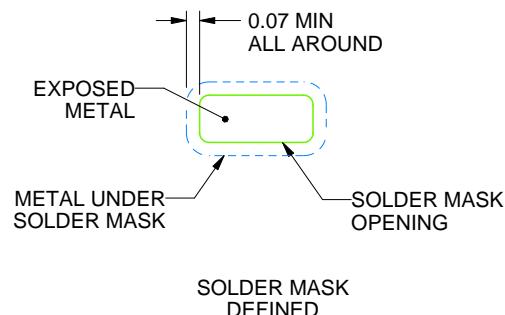
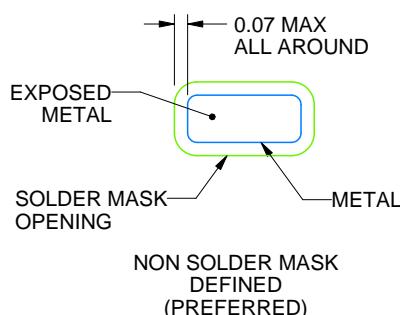
DRV0006D

WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:25X



SOLDER MASK DETAILS

4225563/A 12/2019

NOTES: (continued)

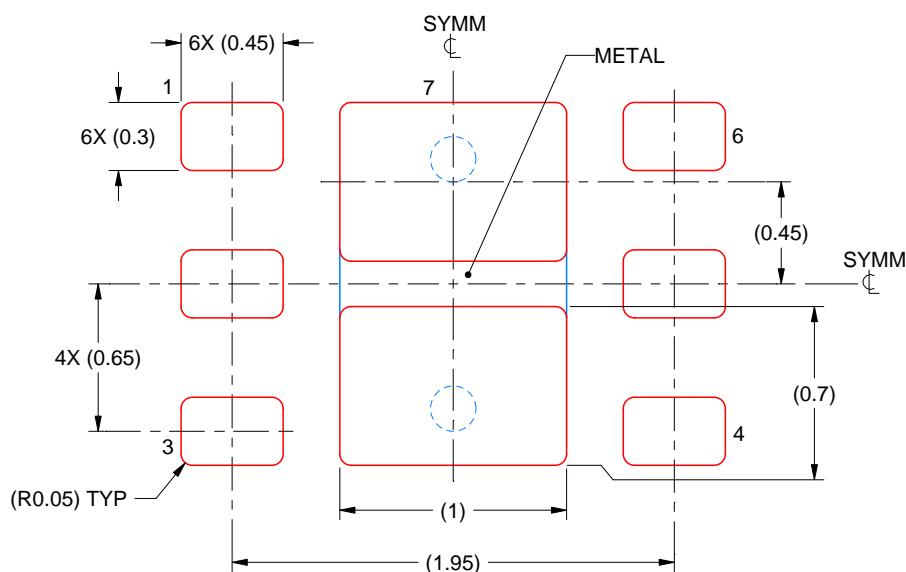
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If some or all are implemented, recommended via locations are shown.

EXAMPLE STENCIL DESIGN

DRV0006D

WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

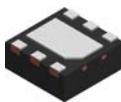
EXPOSED PAD #7
88% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:30X

4225563/A 12/2019

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

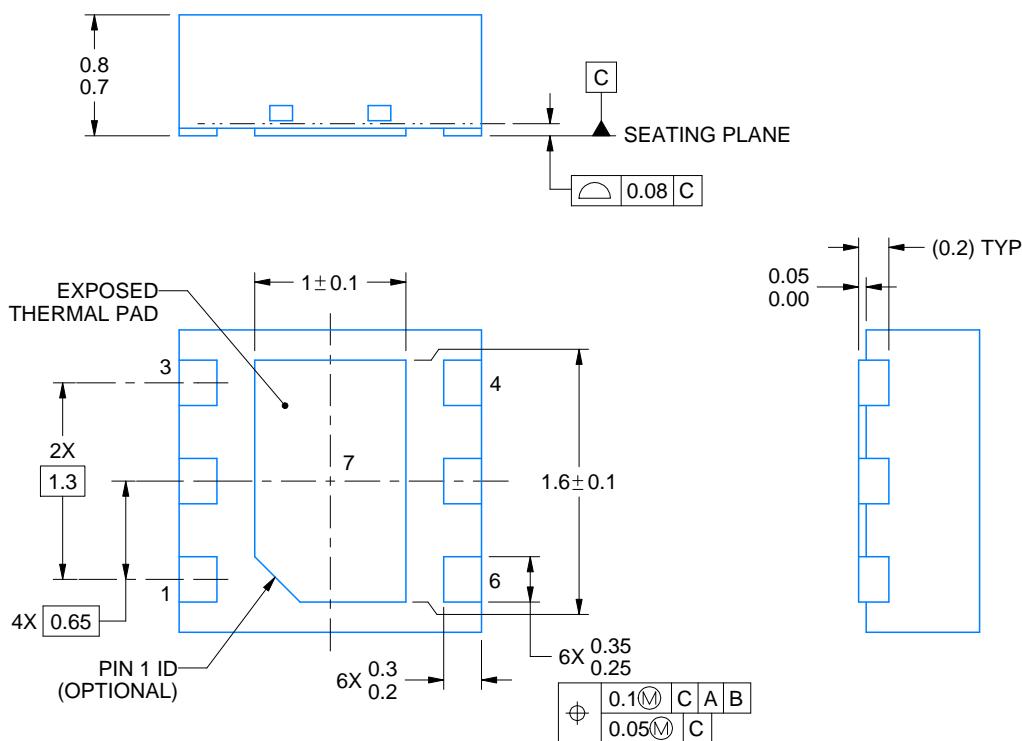
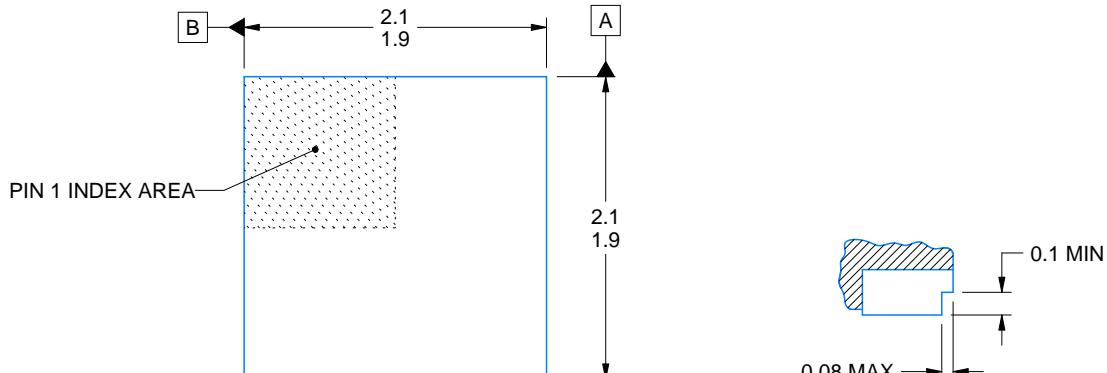
DRV0006A



PACKAGE OUTLINE

WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



4222173/C 11/2025

NOTES:

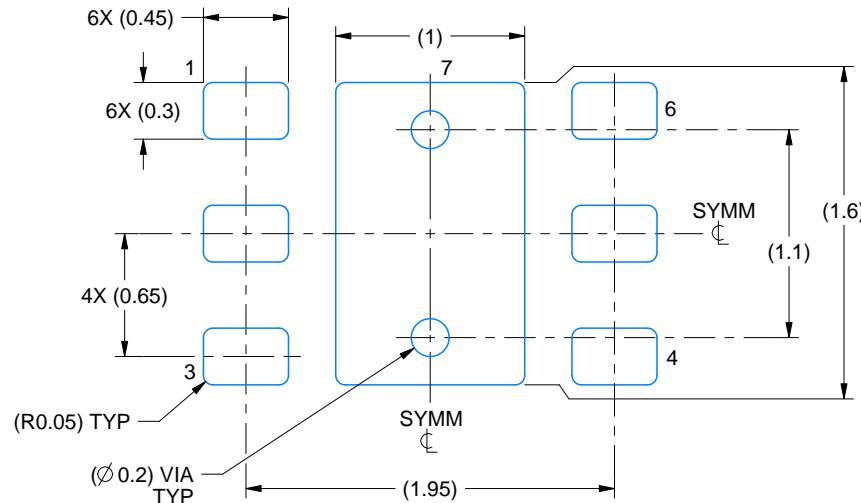
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.
4. Minimum 0.1 mm solder wetting on pin side wall. Available for wettable flank version only.

EXAMPLE BOARD LAYOUT

DRV0006A

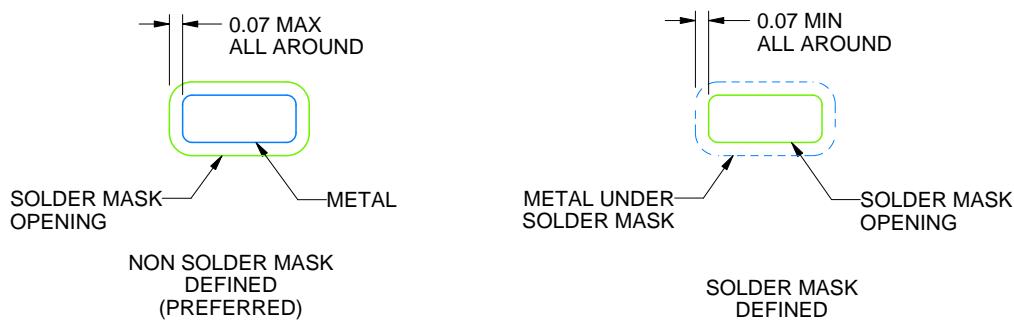
WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE

SCALE:25X



SOLDER MASK DETAILS

4222173/C 11/2025

NOTES: (continued)

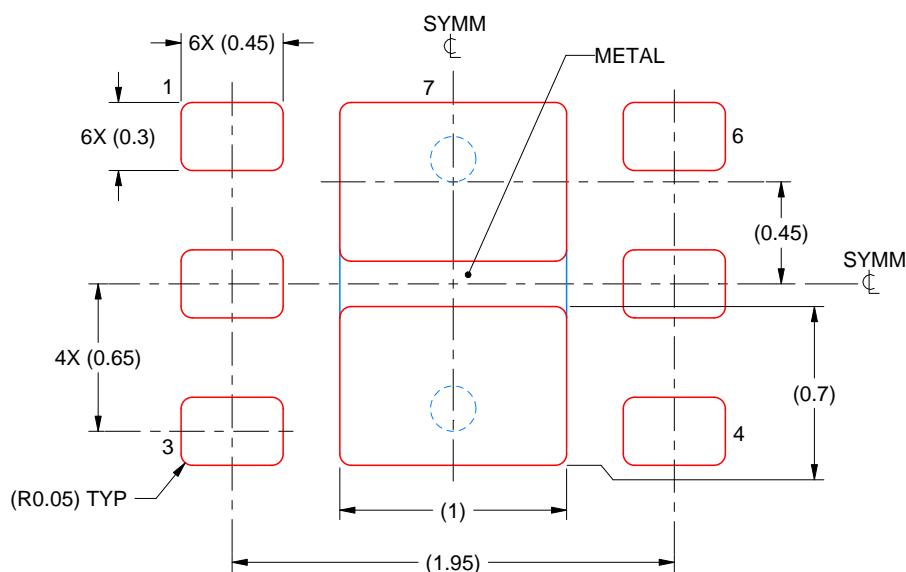
5. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
6. Vias are optional depending on application, refer to device data sheet. If some or all are implemented, recommended via locations are shown.

EXAMPLE STENCIL DESIGN

DRV0006A

WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD #7
88% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:30X

4222173/C 11/2025

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you fully indemnify TI and its representatives against any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to [TI's Terms of Sale](#), [TI's General Quality Guidelines](#), or other applicable terms available either on [ti.com](#) or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products. Unless TI explicitly designates a product as custom or customer-specified, TI products are standard, catalog, general purpose devices.

TI objects to and rejects any additional or different terms you may propose.

Copyright © 2026, Texas Instruments Incorporated

Last updated 10/2025